

TPS61098x 具有集成 LDO/负载开关的超低静态电流同步升压转换器

1 特性

- 低功耗模式下具有 300nA 超低 I_Q
- 负载的启动输入电压为 0.7V
- 工作输入电压范围：0.7V 至 4.5V
- 可选输出电压最高达 4.3V
- 最小开关峰值电流限值为 350mA
- 集成低压降稳压器 (LDO)/负载开关
- 两种模式，由 MODE 引脚控制
 - 工作模式：双输出均处于设定值
 - 低功耗模式：LDO/负载开关关闭；升压转换器保持开启状态
- 自动直通
- 在 10 μ A 负载条件下进行 2V 至 3.3V 转换时的效率高达 88%（低功耗模式）
- 在 5mA 至 100mA 负载条件下进行 2V 至 3.3V 转换时的效率高达 93%
- 1.5mm x 1.5mm 晶圆级小外形无引线 (WSON) 封装

2 应用

- 智能远程控制
- 蓝牙低功耗 (BLE) 标签
- 可穿戴应用
- 低功耗无线应用
- 便携式消费类或医疗产品
- 由单节纽扣电池、单节或双节碱性电池供电的应用

3 说明

TPS61098x 可以由单节或双节碱性电池、镍镉 (NiCd) 电池或镍氢 (NiMH) 电池、单节纽扣电池、单节锂离子电池或锂聚合物电池供电的产品提供超低功耗解决方案。该器件集成了低压降线性稳压器 (LDO) 或者带有升压转换器的负载开关，并且提供有双输出电源轨。升压转换器输出 $V_{(MAIN)}$ 用作主系统的电源并且始终开启，LDO 或负载开关输出 $V_{(SUB)}$ 则为外设供电。

TPS61098x 具有两种模式：工作模式和低功耗模式（由 MODE 引脚控制）。在工作模式下，两输出均启用并具有增强的响应性能。在低功耗模式下，LDO 或负载开关被禁用，断开与外设的连接。在低功耗模式下，TPS61098x 仅消耗 300nA 静态电流，10 μ A 负载条件下效率高达 88%。

TPS61098x 支持自动直通功能。当输入电压高于直通阈值时，升压转换器停止开关并将输入电压传送到 VMAIN 轨；当输入电压低于该阈值时，升压转换器工作在升压模式并将输出稳压至目标值。TPS61098x 针对不同的输出设定值提供了多种版本。

在 0.7V 输入到 3.3V 输出的转换过程中，TPS61098x 可提供高达 50mA 的总输出电流。该升压转换器基于滞后控制器拓扑结构，可利用同步整流器以最低的静态电流实现最高效率。

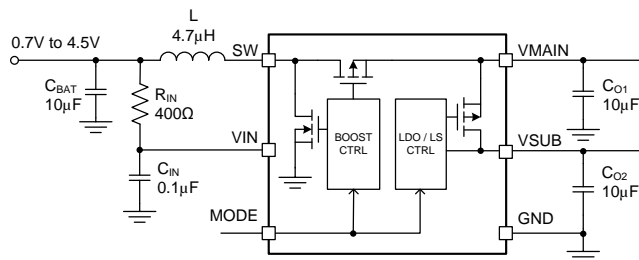
TPS61098x 采用 1.5mm x 1.5mm WSON 封装实现小型电路布局。

器件信息(1)

器件型号	封装	封装尺寸 (标称值)
TPS61098x	6 引脚 WSON	1.50mm x 1.50mm

(1) 要了解所有可用封装，请见本文档末尾的可订购产品附录。

简化电路原理图



目录

1	特性	1	8.4	Device Functional Modes	18
2	应用	1	9	Applications and Implementation	20
3	说明	1	9.1	Application Information	20
4	修订历史记录	2	9.2	Typical Applications	20
5	Device Comparison Table	4	10	Power Supply Recommendations	30
6	Pin Configuration and Functions	4	11	Layout	31
7	Specifications	5	11.1	Layout Guidelines	31
7.1	Absolute Maximum Ratings	5	11.2	Layout Example	31
7.2	ESD Ratings	5	12	器件和文档支持	32
7.3	Recommended Operating Conditions	5	12.1	器件支持	32
7.4	Thermal Information	5	12.2	文档支持	32
7.5	Electrical Characteristics	6	12.3	相关链接	32
7.6	Typical Characteristics	8	12.4	社区资源	32
8	Detailed Description	15	12.5	商标	32
8.1	Overview	15	12.6	静电放电警告	32
8.2	Functional Block Diagrams	15	12.7	Glossary	32
8.3	Feature Description	16	13	机械、封装和可订购信息	32

4 修订历史记录

Changes from Revision A (July 2015) to Revision B

Page

•	Added devices TPS610985DSE and TPS610986DSE to the <i>Device Comparison Table</i>	4
•	Added device TPS610982 to the <i>Electrical Characteristics</i>	6
•	Added 图 3 and 图 4	8
•	Added 图 11 and 图 12	8
•	Added 图 18 and 图 19	9
•	Added 图 24 and 图 25	10
•	Added 图 28 and 图 29	11
•	Added 图 33 and 图 34	12
•	Added 图 37 and 图 38	13
•	Added text to the <i>Overview</i> section: "The TPS610982 is an exception..."	15
•	Added text to the <i>Low Power Mode</i> Section: "The TPS610982 is an exception..."	19
•	Added 图 70, 图 71, 图 72 and 图 74	29
•	Added 图 76 and 图 77	29

Changes from Original (June 2015) to Revision A

Page

•	已将 <i>说明</i> 中的文本由“效率可达 80%”更改为“效率高达 88%”	1
•	已将 <i>简化电路原理图</i> 中的“LDO/LS CTRL”更改为“LDO/LS CTRL”，4.7μF 更改为 4.7μH	1
•	Changed $V_{(Dropout)}$ in the <i>Electrical Characteristics</i> From: TPS61098 and TPS610981 To: TPS6198x	6
•	Changed $V_{IN} = 1.2\text{ V}$ To $V_{IN} = 1.5\text{ V}$ and $V_{IN} = 2\text{ V}$ to $V_{IN} = 2.5\text{ V}$ in 图 15	9
•	Changed "Boost Efficiency" To: "Boost Output Voltage" in 图 20 To 图 23	10
•	Changed text "below the programmed threshold," To: "below the programmed threshold with a hysteresis," in <i>Thermal Shutdown</i>	18
•	Changed text "unstable operation at IC temperatures at the overtemperature threshold." To: "unstable operation at the overtemperature threshold." in <i>Thermal Shutdown</i>	18
•	Changed text "sense or transfer signals" To: sense or transmit signals" in <i>VMAIN to Power MCU and VSUB to Power Subsystem</i>	20

- Changed 4.7 μ F To 4.7 μ H in [图 43](#) 20
- Changed text "TPS610981 enters into sleep mode" To: "TPS610981 enters into Low Power mode" in [Control Sequence](#) 23
- Changed 4.7 μ F To 4.7 μ H in [图 63](#) 27
- Changed text "a boost converter and an LDO are needed: To: "a boost converter with an LDO is needed" in [图 67](#)..... 28
- Changed 4.7 μ F To 4.7 μ H in [图 67](#) 28

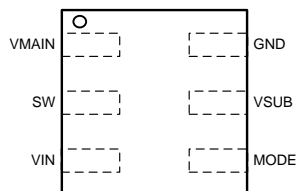
5 Device Comparison Table

PART NUMBER	INTEGRATED LDO OR LOAD SWITCH	VMAIN (ACTIVE MODE)	VMAIN (LOW POWER MODE)	VSUB (ACTIVE MODE)	VSUB (LOW POWER MODE)	VSUB ACTIVE DISCHARGE IN LOW POWER MODE
TPS61098DSE ⁽¹⁾	LDO	4.3 V	2.2 V	3.1 V	OFF	No
TPS610981DSE	LDO	3.3 V	3.3 V	3.0 V	OFF	Yes
TPS610982DSE	LDO	3.3 V	3.3 V	2.8 V	2.8 V	No
TPS610985DSE ⁽²⁾	Load Switch	3 V	3 V	ON	OFF	Yes
TPS610986DSE ⁽²⁾	Load Switch	3.3 V	3.3 V	ON	OFF	Yes

- (1) The DSE package is available taped and reeled. Add R suffix to device type (e.g., TPS61098DSER) to order quantities of 3000 devices per reel. Add T suffix to device type (e.g., TPS61098DSET) to order quantities of 250 devices per reel. For detailed ordering information please check the PACKAGE OPTION ADDENDUM section at the end of this datasheet.
- (2) Preview product. Contact TI factory for more information.

6 Pin Configuration and Functions

**DSE Package
6-Pin WSON
Top View**



Pin Functions

PIN NAME	PIN NO.	I/O	DESCRIPTION
VMAIN	1	PWR	Boost converter output
SW	2	PWR	Connection for inductor
VIN	3	I	IC power supply input
MODE	4	I	Mode selection pin. 1: Active mode; 0: Low Power mode. Must be actively tied high or low. Do not leave floating.
VSUB	5	PWR	LDO or load switch output
GND	6	PWR	IC ground

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Input voltage	V _{IN} , SW, V _{MAIN} , V _{SUB}	-0.3	4.7	V
	MODE	-0.3	5.0	V
Operating junction temperature, T _J		-40	150	°C
Storage temperature range, T _{stg}		-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human Body Model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±1000	V
	Charged Device Model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±250	

- (1) JEDEC document JEP155 states that 500V HBM rating allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM rating allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage range	0.7		4.5	V
V _(MAIN)	Boost converter output voltage range	2.2		4.3	V
V _(SUB)	Load switch / LDO output voltage range	1.8		3.7	V
L	Effective inductance range	1.54	4.7	6.11	μH
C _{BAT}	Effective input capacitance range at input ⁽¹⁾	5			μF
C _{O1}	Effective output capacitance range at V _{MAIN} pin for boost converter output ⁽¹⁾	5	10	22	μF
C _{O2}	Effective output capacitance range at V _{SUB} pin for LDO output ⁽¹⁾	1 ⁽²⁾	5	10	μF
	Effective output capacitance range at V _{SUB} pin for load switch output ⁽¹⁾⁽³⁾		1	2.2	μF
T _J	Operating virtual junction temperature	-40		125	°C

- (1) Effective value. Ceramic capacitor's derating effect under bias should be considered. Choose the right nominal capacitance by checking capacitor DC bias characteristics.
(2) If LDO output current is lower than 20 mA, the minimum effective output capacitance value can be lower to 0.5 μF.
(3) With load switch version, the output capacitor at V_{SUB} pin is only required if smaller voltage ripple is needed.

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS61098x	UNIT
		DSE 6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	207.3	°C/W
R _{θJctop}	Junction-to-case (top) thermal resistance	118.9	
R _{θJB}	Junction-to-board thermal resistance	136.4	
Ψ _{JT}	Junction-to-top characterization parameter	8.3	
Ψ _{JB}	Junction-to-board characterization parameter	136.4	
R _{θJcbot}	Junction-to-case (bottom) thermal resistance	N/A	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).

7.5 Electrical Characteristics

$T_J = -40^\circ\text{C}$ to 125°C and $V_{IN} = 0.7\text{ V}$ to 4.5 V . Typical values are at $V_{IN} = 1.5\text{ V}$, $T_J = 25^\circ\text{C}$, unless otherwise noted.

PARAMETER		VERSION	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Supply							
V_{IN}	Input voltage range	TPS61098x		0.7		4.5	V
$V_{IN(\text{start})}$	Minimum input voltage at startup	TPS61098x	$R_{\text{Load}} \geq 3\text{ k}\Omega$ ⁽¹⁾			0.7	V
$I_{Q(\text{VIN})}$	Quiescent current into VIN pin in Active Mode	TPS61098x	MODE = High, Boost or Pass-through No Load, No Switching $T_J = -40^\circ\text{C}$ to 85°C		2	4	μA
	Quiescent current into VIN pin in Low Power Mode	TPS61098x	MODE = Low, Boost or Pass-through No Load, No Switching		5	90	nA
$I_{Q(\text{VMAIN})}$	Quiescent current into VMAIN pin in Active Mode	TPS61098/1	MODE = High, Boost or Pass-through No Load, No Switching $T_J = -40^\circ\text{C}$ to 85°C		15	23	μA
		TPS610982	MODE = High, Boost or Pass-through No Load, No Switching $T_J = -40^\circ\text{C}$ to 85°C		18	23	μA
	Quiescent current into VMAIN pin in Low Power Mode	TPS61098/1	MODE = Low, Boost or Pass-through No Load, No Switching $T_J = 25^\circ\text{C}$		300	400	nA
			MODE = Low, Boost or Pass-through No Load, No Switching $T_J = -40^\circ\text{C}$ to 85°C		300	800	nA
		TPS610982	MODE = Low, Boost or Pass-through No Load, No Switching $T_J = -40^\circ\text{C}$ to 85°C		4	10	μA
$I_{\text{LKG}(\text{SW})}$	Leakage current of SW pin (from SW pin to GND pin)	TPS61098x	$V_{(\text{MAIN})} = V_{(\text{SW})} = 4.7\text{ V}$, No Load $T_J = -40^\circ\text{C}$ to 85°C		5	100	nA
$I_{\text{LKG}(\text{MAIN})}$	Leakage current of VMAIN pin (from VMAIN pin to SW pin)	TPS61098x	$V_{(\text{MAIN})} = 4.7\text{ V}$, $V_{(\text{SW})} = 0\text{ V}$, No Load $T_J = -40^\circ\text{C}$ to 85°C		10	200	nA
$I_{\text{LKG}(\text{SUB})}$	Leakage current of VSUB pin (from VMAIN pin to VSUB pin)	TPS61098/1	MODE = Low, $V_{(\text{MAIN})} = 4.7\text{ V}$, $V_{(\text{SUB})} = 0\text{ V}$ $T_J = -40^\circ\text{C}$ to 85°C		10	150	nA
$I_{\text{LKG}(\text{MODE})}$	Leakage current into MODE pin	TPS61098x	$V_{(\text{MODE})} = 5\text{ V}$ $T_J = -40^\circ\text{C}$ to 85°C		5	30	nA
Power Switch							
$R_{\text{DS(on)_LS}}$	Low side switch on resistance	TPS61098	MODE = Low		600	1000	m Ω
			MODE = High		300	600	m Ω
		TPS610981/2	MODE = Low / High		350	650	m Ω
$R_{\text{DS(on)_HS}}$	Rectifier on resistance	TPS61098	MODE = Low		700	1000	m Ω
			MODE = High		450	700	m Ω
		TPS610981/2	MODE = Low / High		500	700	m Ω
$V_{(\text{Dropout})}$	LDO dropout voltage	TPS61098x	$I_{\text{SUB}} = 50\text{ mA}$		60	100	mV
I_{LH}	Inductor current ripple	TPS61098x			100		mA
$I_{\text{LIM}(\text{BST})}$	Boost switch current limit	TPS61098x	$0.7\text{ V} < V_{\text{IN}} < V_{(\text{MAIN})}$	350	500	650	mA
$I_{\text{LIM}(\text{SUB})}$	VSUB output current limit	TPS61098x	$T_J = -20^\circ\text{C}$ to 125°C	200			mA
$I_{(\text{DISCH})}$	Discharge current from VSUB pin to GND pin	TPS610981	MODE = Low, $V_{(\text{SUB})} = 3\text{ V}$	5	8		mA
Output							

(1) TPS61098x is able to drive $R_{\text{Load}} > 150\ \Omega$ after V_{MAIN} is established over 1.8 V .

Electrical Characteristics (continued)
 $T_J = -40^{\circ}\text{C}$ to 125°C and $V_{IN} = 0.7\text{ V}$ to 4.5 V . Typical values are at $V_{IN} = 1.5\text{ V}$, $T_J = 25^{\circ}\text{C}$, unless otherwise noted.

PARAMETER	VERSION	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(\text{MAIN})}$ Boost converter output voltage	TPS61098	MODE = High, $V_{IN} < V_{(\text{PSTH})}$ Burst mode, open loop		4.45		V
		MODE = High, $V_{IN} < V_{(\text{PSTH})}$ PWM mode, open loop	4.142	4.27	4.398	V
		MODE = Low, $V_{IN} < V_{(\text{PSTH})}$ Burst mode, open loop		2.3		V
		MODE = Low, $V_{IN} < V_{(\text{PSTH})}$ PWM mode, open loop	2.163	2.23	2.297	V
	TPS610981	MODE = High / Low, $V_{IN} < V_{(\text{PSTH})}$ Burst mode, open loop		3.4		V
		MODE = High / Low, $V_{IN} < V_{(\text{PSTH})}$ PWM mode, open loop	3.201	3.3	3.399	V
	TPS610982	MODE = High / Low, $V_{IN} < V_{(\text{PSTH})}$ Burst mode, open loop		3.4		V
		MODE = High / Low, $V_{IN} < V_{(\text{PSTH})}$ PWM mode, open loop	3.201	3.3	3.399	V
$V_{(\text{SUB})}$ LDO output voltage (LDO version)	TPS61098	MODE = High	3.038	3.1	3.162	V
	TPS610981	MODE = High	2.94	3.0	3.06	V
	TPS610982	MODE = High / Low	2.744	2.8	2.856	V
$V_{(\text{PSTH})}$ Pass-through mode threshold	TPS61098	MODE = High, V_{IN} rising		4.4		V
		MODE = High, Hysteresis		0.1		V
		MODE = Low, V_{IN} rising		2.25		V
		MODE = Low, Hysteresis		0.1		V
	TPS610981	MODE = High / Low, V_{IN} rising		3.35		V
		MODE = High / Low, Hysteresis		0.1		V
	TPS610982	MODE = High / Low, V_{IN} rising		3.35		V
		MODE = High / Low, Hysteresis		0.1		V
PSRR Power-supply rejection ratio from LDO input to output	TPS61098/1/2	$f = 1\text{ kHz}$, $C_{O2} = 10\text{ }\mu\text{F}$, $I_{\text{SUB}} = 10\text{ mA}$ MODE = High		40		dB
	TPS610982	$f = 1\text{ kHz}$, $C_{O2} = 10\text{ }\mu\text{F}$, $I_{\text{SUB}} = 10\text{ mA}$ MODE = Low		28		dB
$t_{\text{stup_LDO}}$ LDO startup time	TPS61098x	No Load Time from MODE high to 90% of $V_{(\text{SUB})}$		1		ms
Control Logic						
V_{IL} MODE input low voltage	TPS61098x				0.4	V
V_{IH} MODE input high voltage	TPS61098x		1.2			V
Overtemperature protection	TPS61098x			150		$^{\circ}\text{C}$
Overtemperature hysteresis	TPS61098x			25		$^{\circ}\text{C}$

7.6 Typical Characteristics

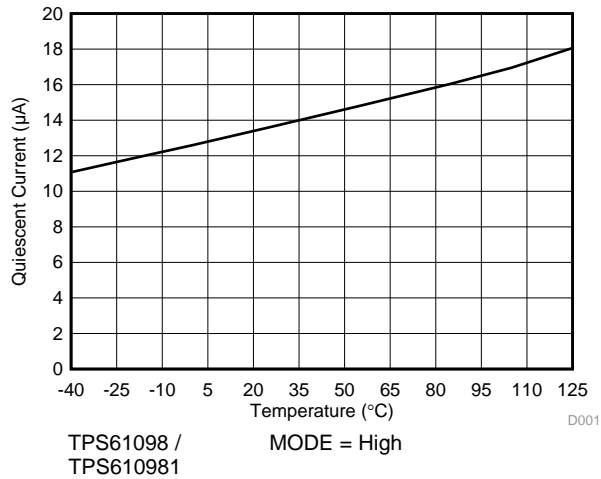


图 1. I_Q into VMAIN Pin at Active Mode vs Temperature

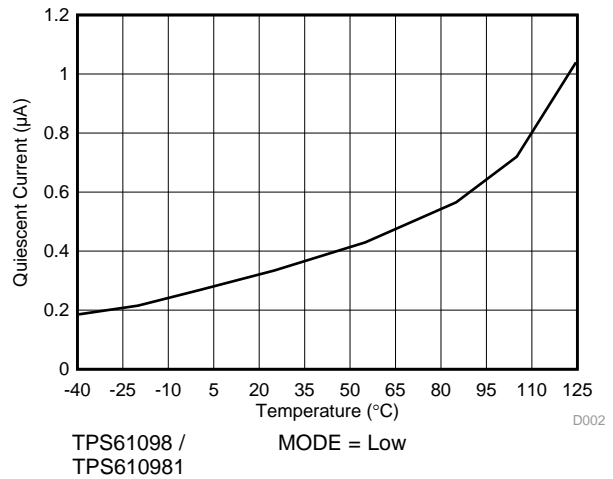


图 2. I_Q into VMAIN Pin at Low Power Mode vs Temperature

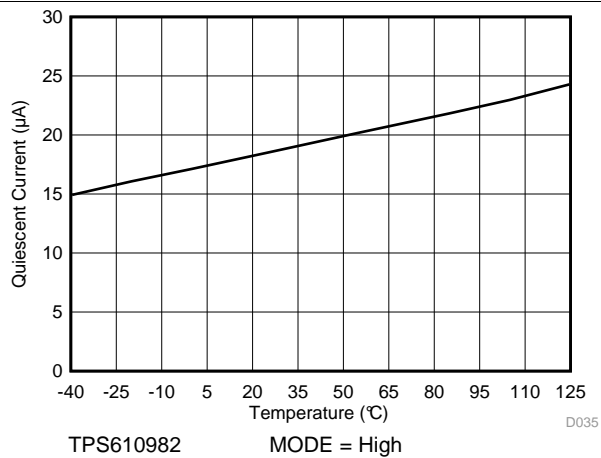


图 3. I_Q into VMAIN Pin at Active Mode vs Temperature

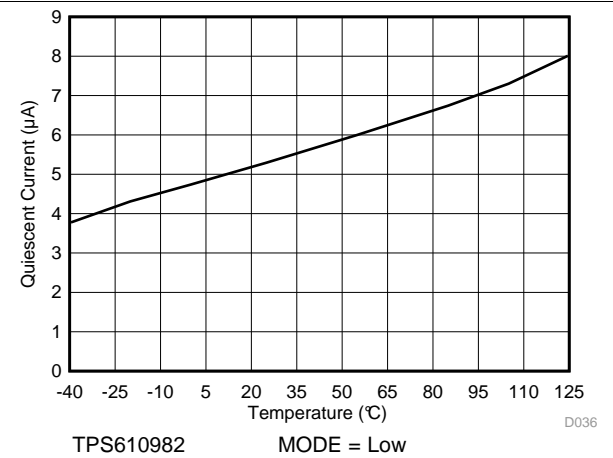


图 4. I_Q into VMAIN Pin at Low Power Mode vs Temperature

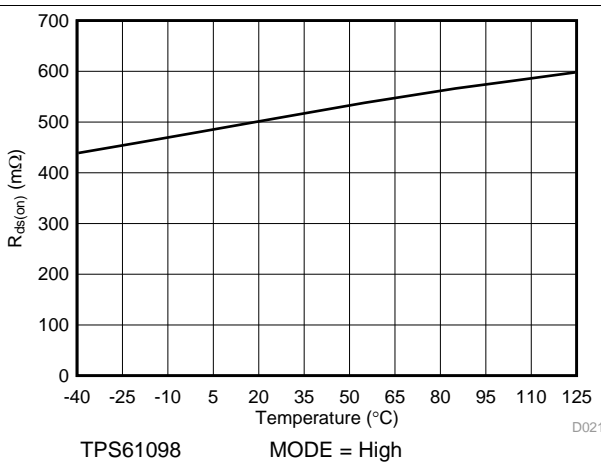


图 5. Rectifier On Resistance vs Temperature

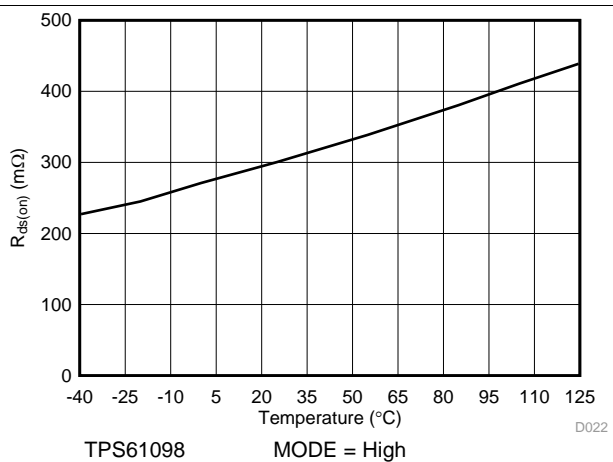


图 6. Low Side Switch On Resistance vs Temperature

Typical Characteristics (接下页)

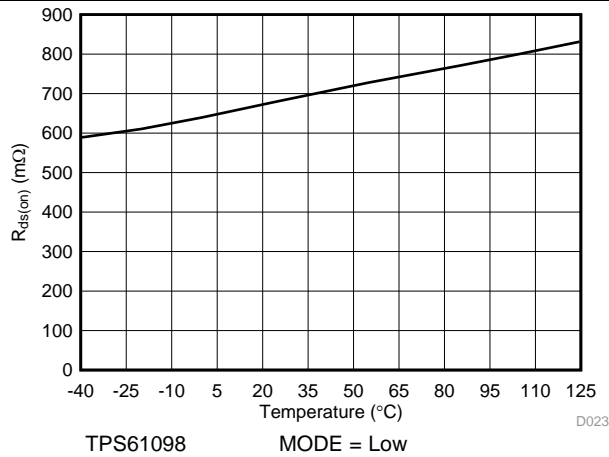


图 7. Rectifier On Resistance vs Temperature

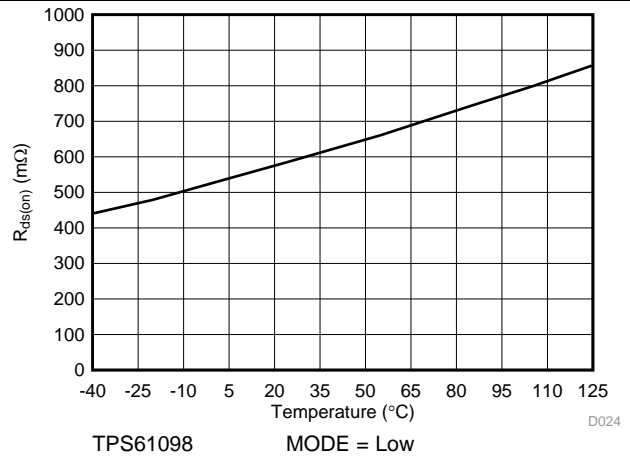


图 8. Low Side Switch On Resistance vs Temperature

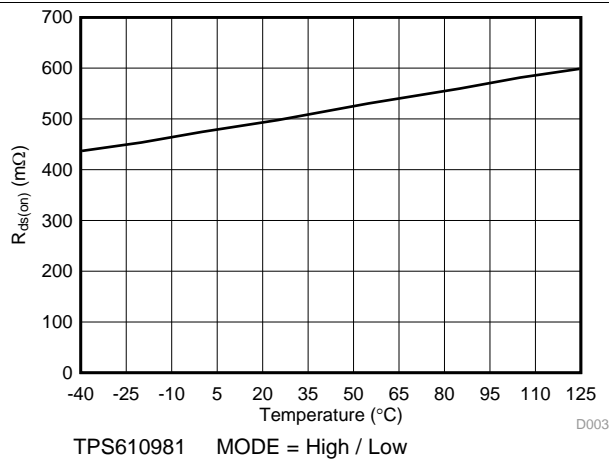


图 9. Rectifier On Resistance vs Temperature

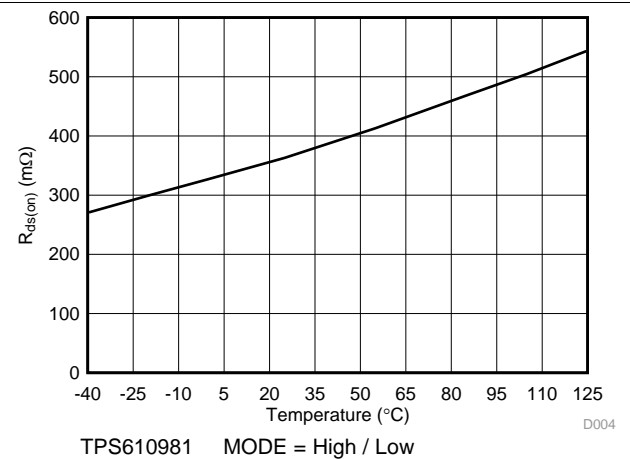


图 10. Low Side Switch On Resistance vs Temperature

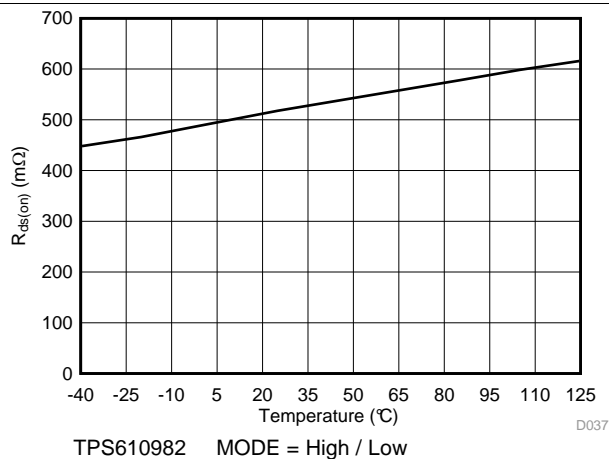


图 11. Rectifier On Resistance vs Temperature

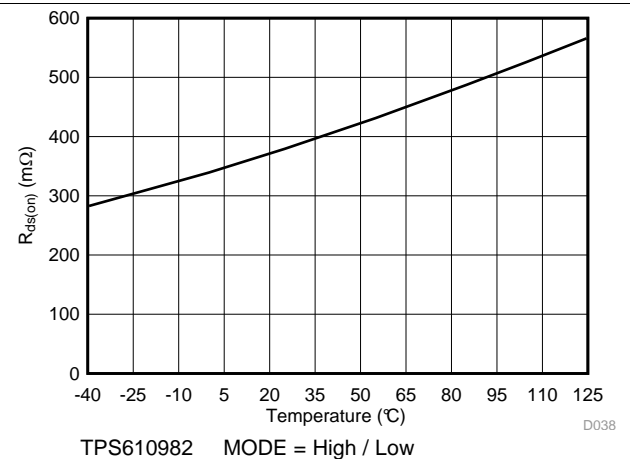
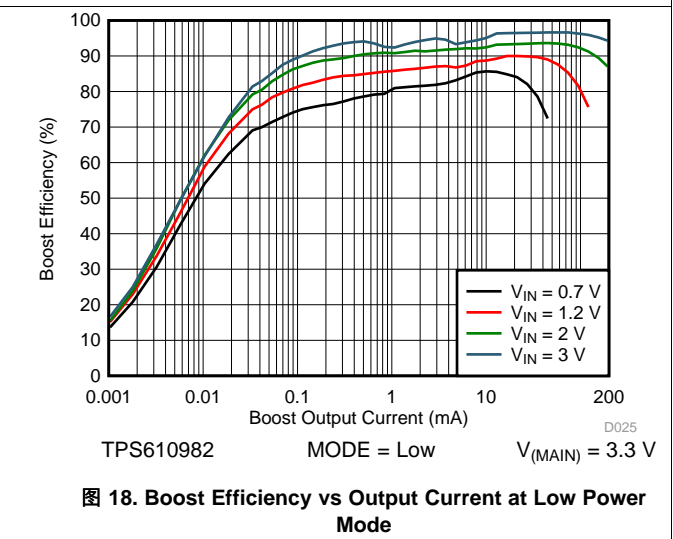
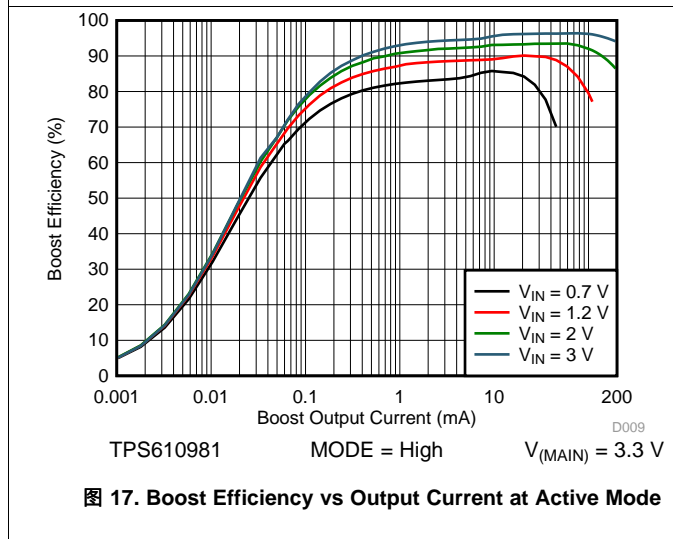
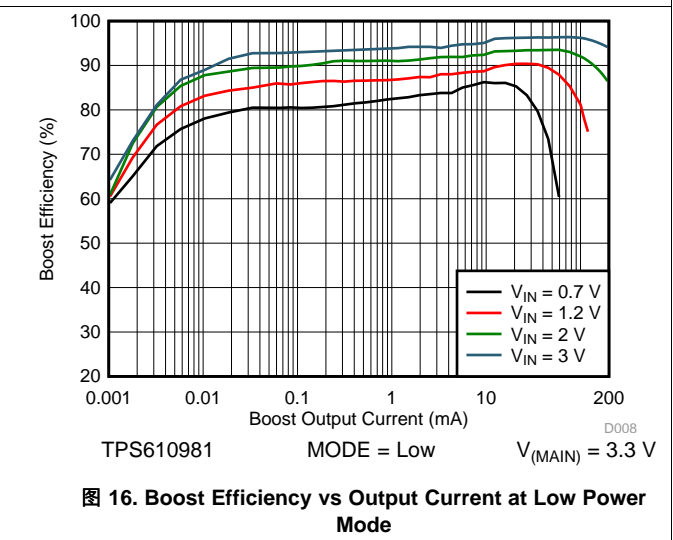
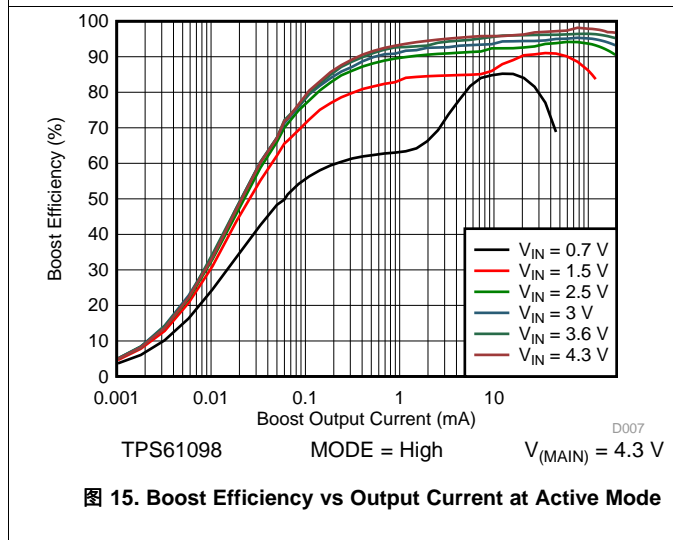
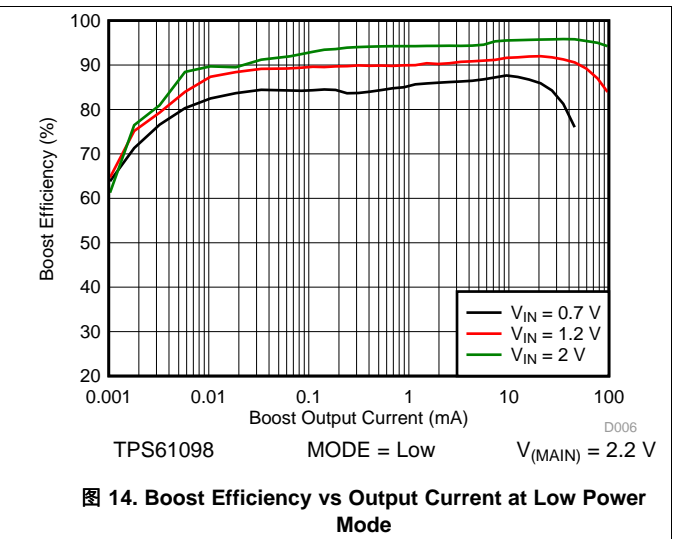
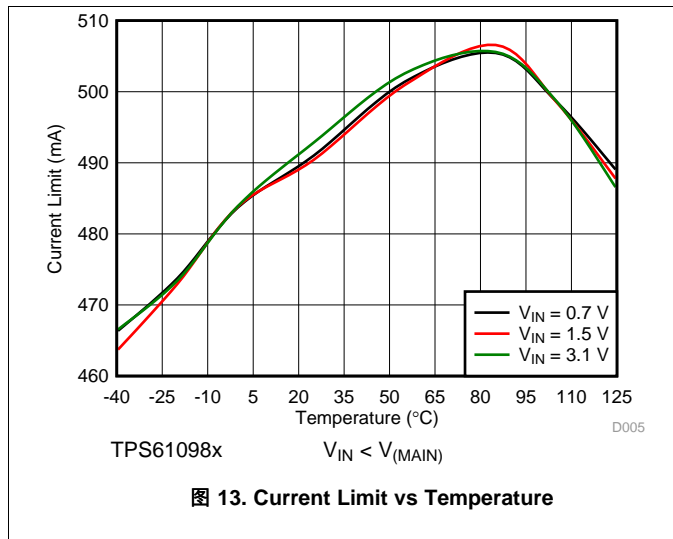


图 12. Low Side Switch On Resistance vs Temperature

Typical Characteristics (接下页)



Typical Characteristics (接下页)

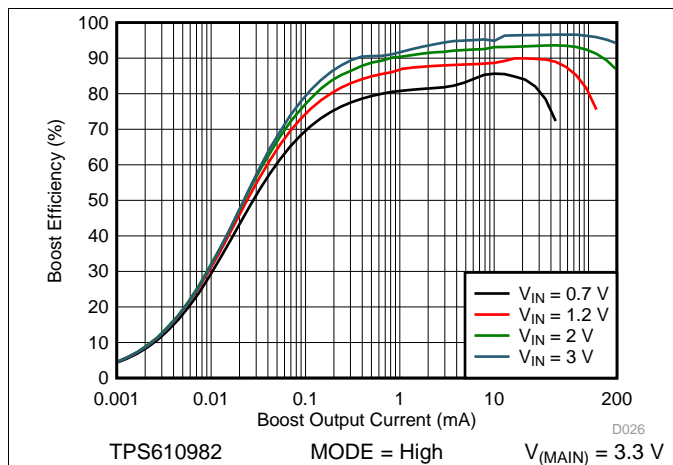


图 19. Boost Efficiency vs Output Current at Active Mode

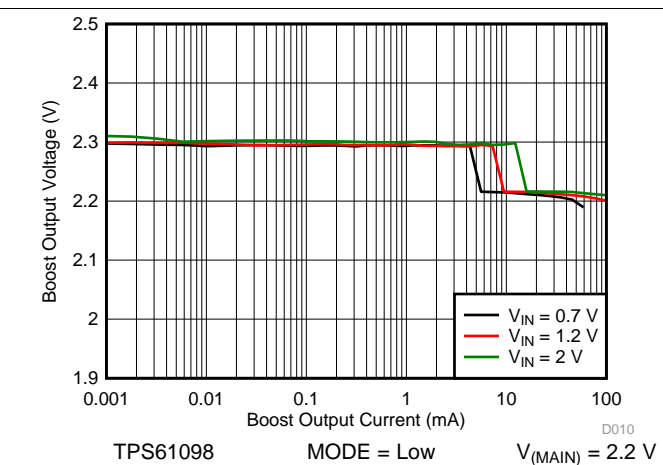


图 20. Boost Load Regulation at Low Power Mode

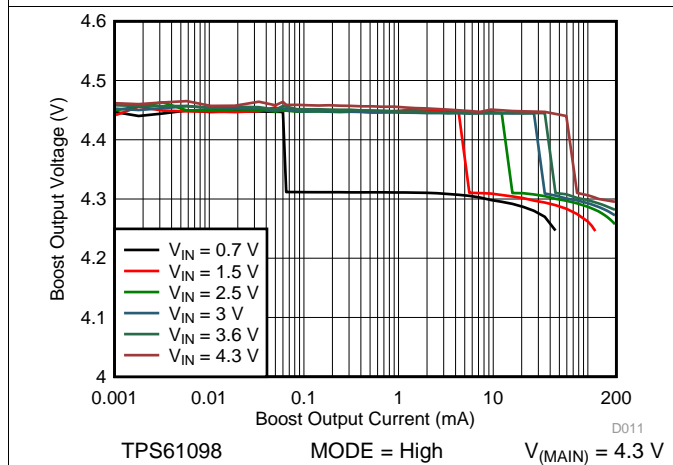


图 21. Boost Load Regulation at Active Mode

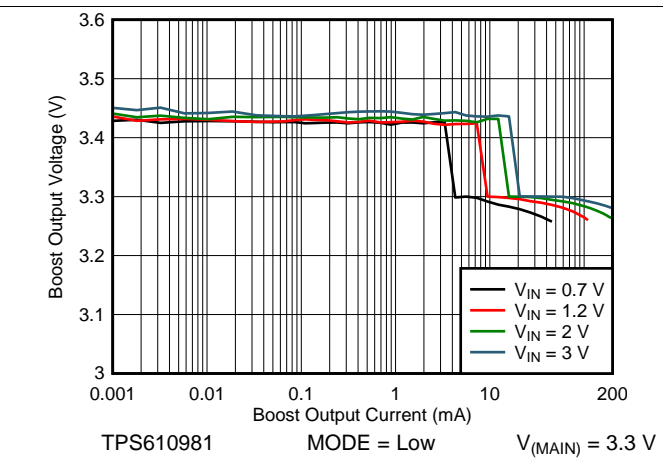


图 22. Boost Load Regulation at Low Power Mode

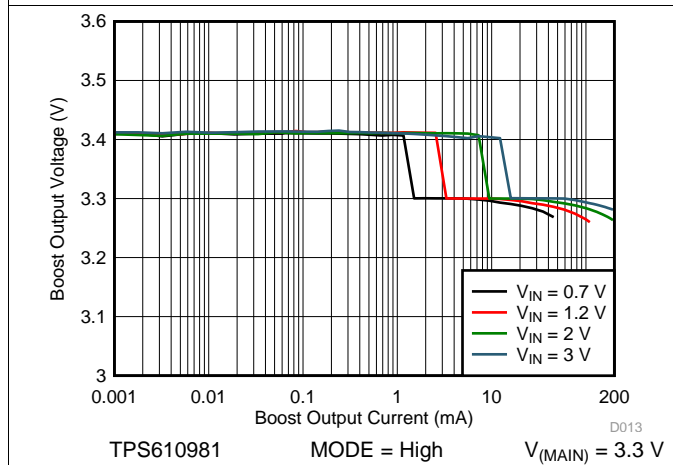


图 23. Boost Load Regulation at Active Mode

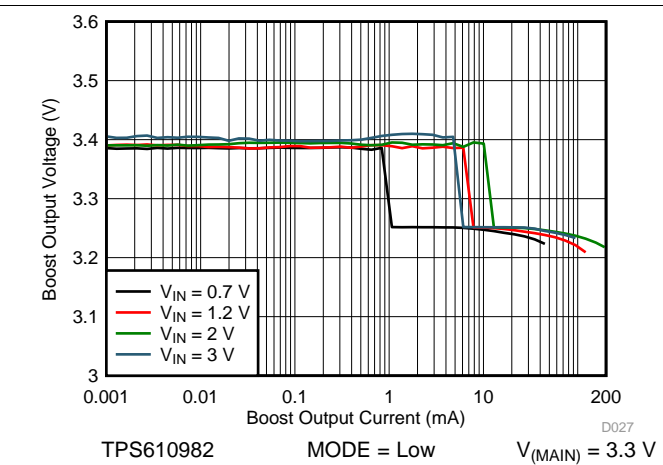


图 24. Boost Load Regulation at Low Power Mode

Typical Characteristics (接下页)

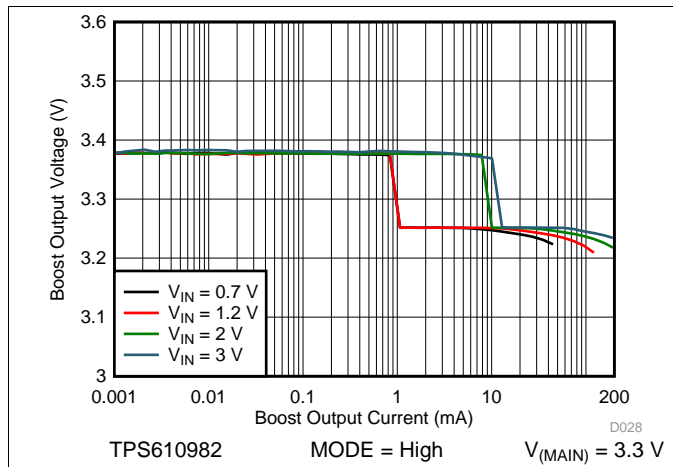


图 25. Boost Load Regulation at Active Mode

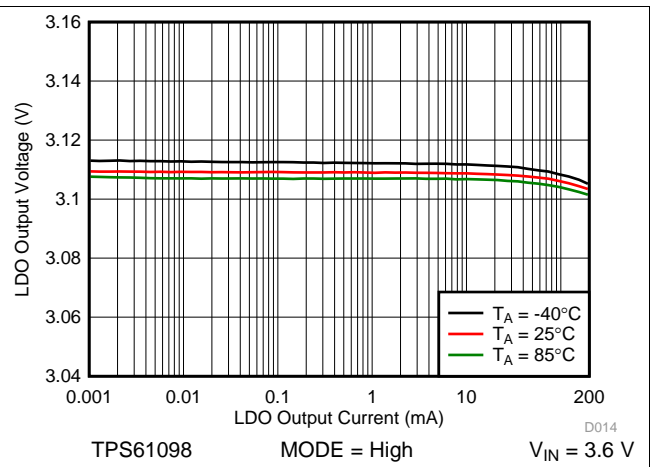


图 26. LDO Load Regulation

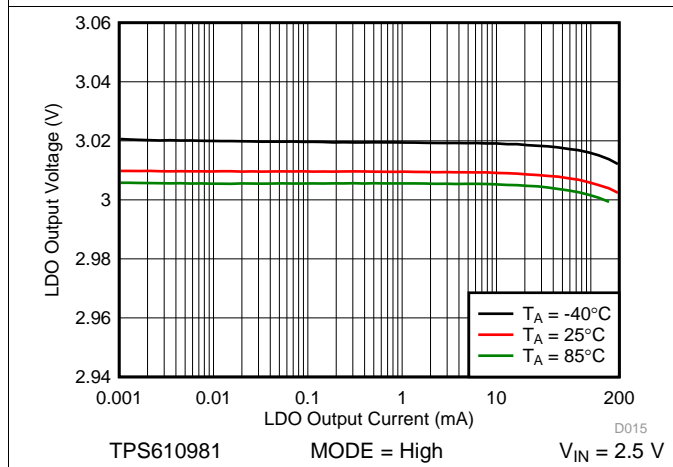


图 27. LDO Load Regulation

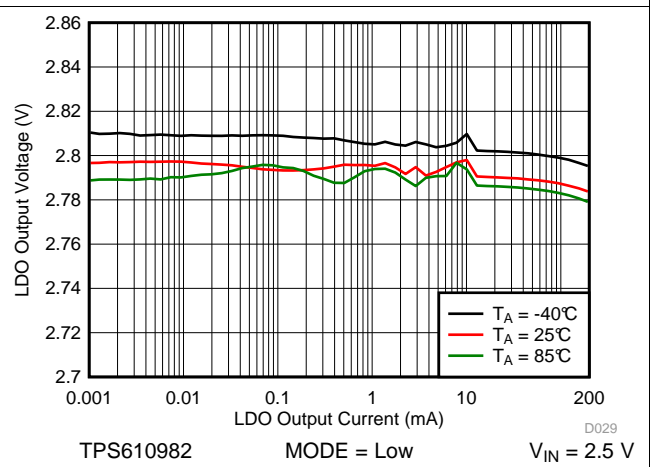


图 28. LDO Load Regulation at Low Power Mode

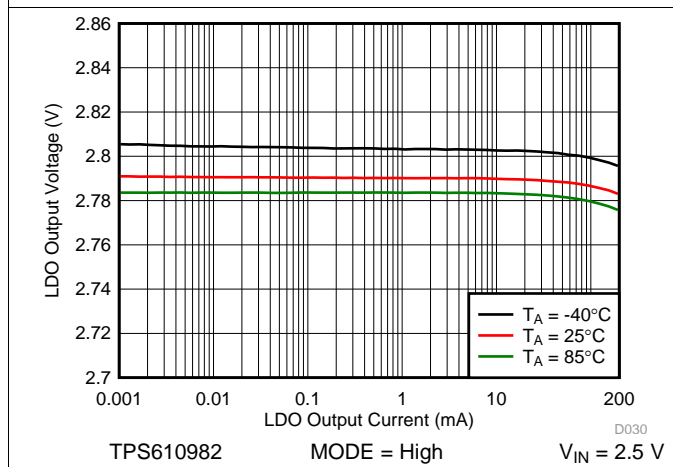


图 29. LDO Load Regulation at Active Mode

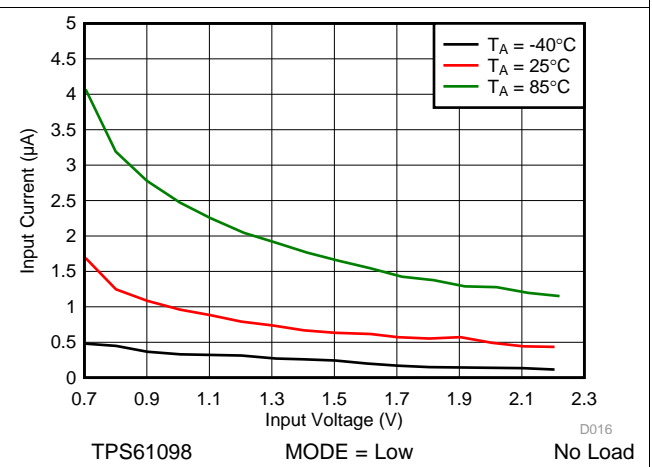


图 30. No Load Input Current vs Input Voltage at Low Power Mode

Typical Characteristics (接下页)

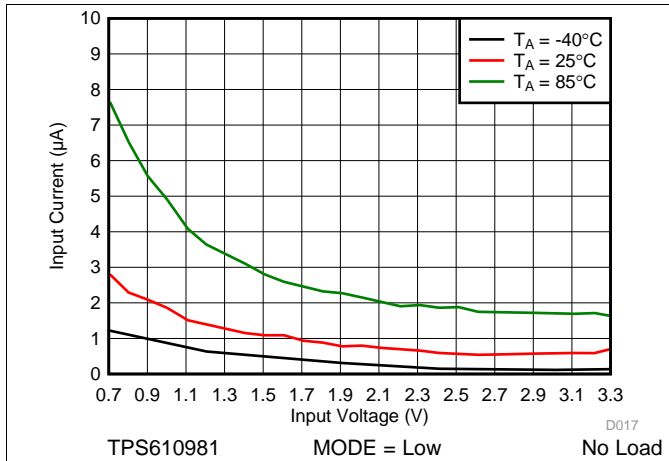


图 31. No Load Input Current vs Input Voltage at Low Power Mode

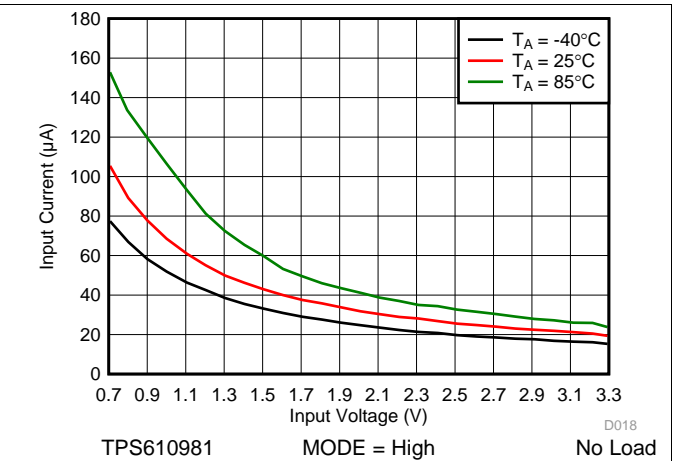


图 32. No Load Input Current vs Input Voltage at Active Mode

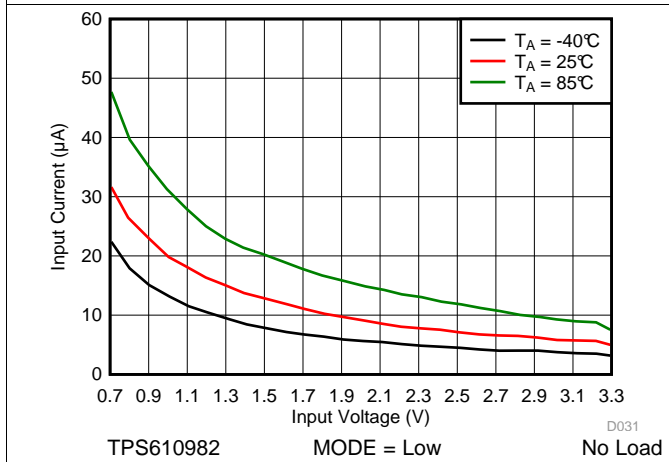


图 33. No Load Input Current vs Input Voltage at Low Power Mode

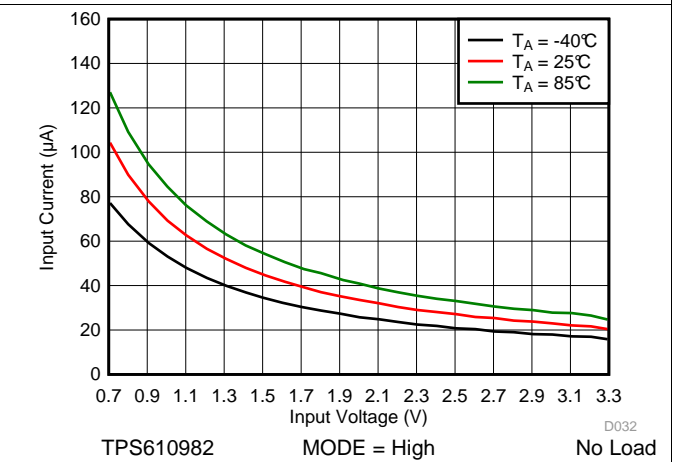


图 34. No Load Input Current vs Input Voltage at Active Mode

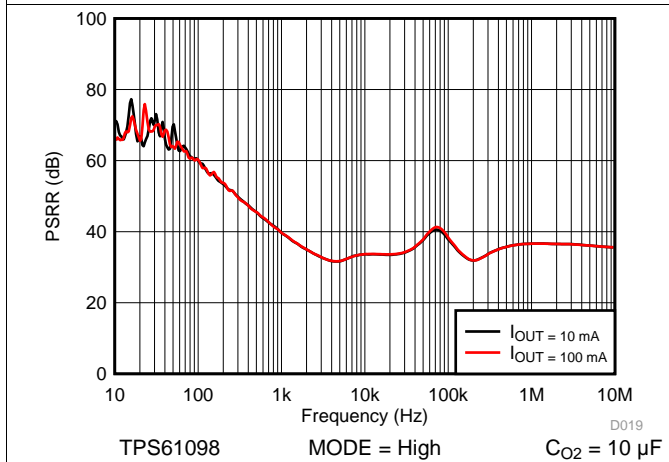


图 35. LDO PSRR vs Frequency

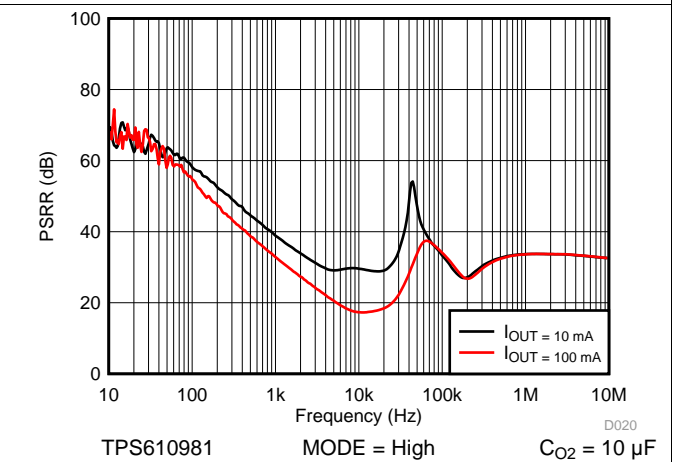
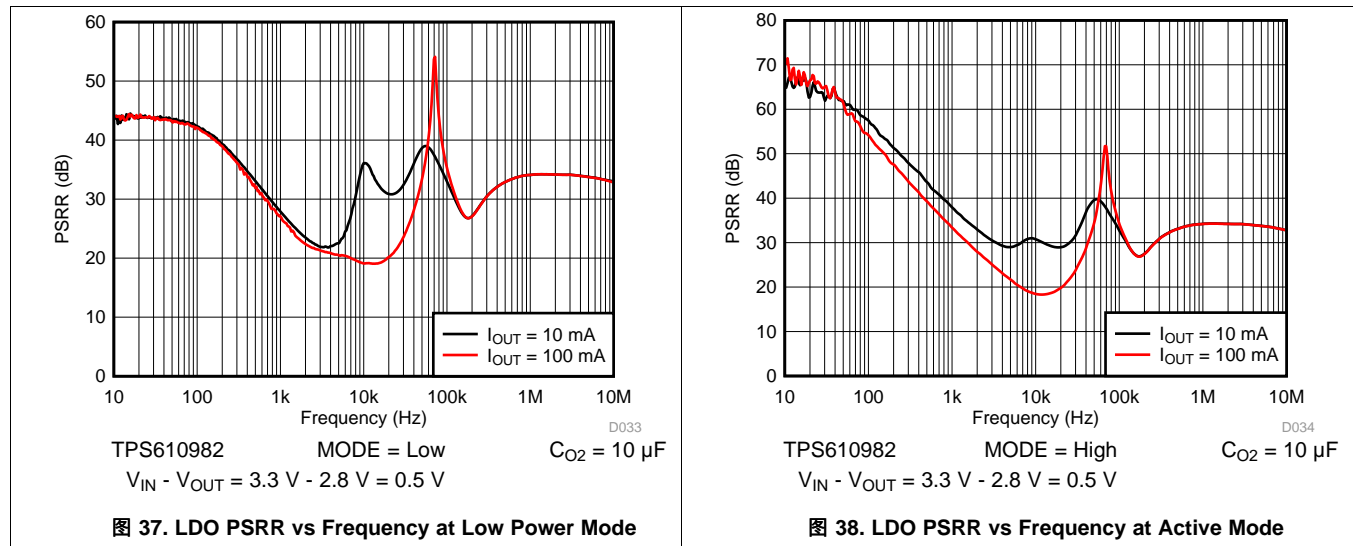


图 36. LDO PSRR vs Frequency

Typical Characteristics (接下页)



8 Detailed Description

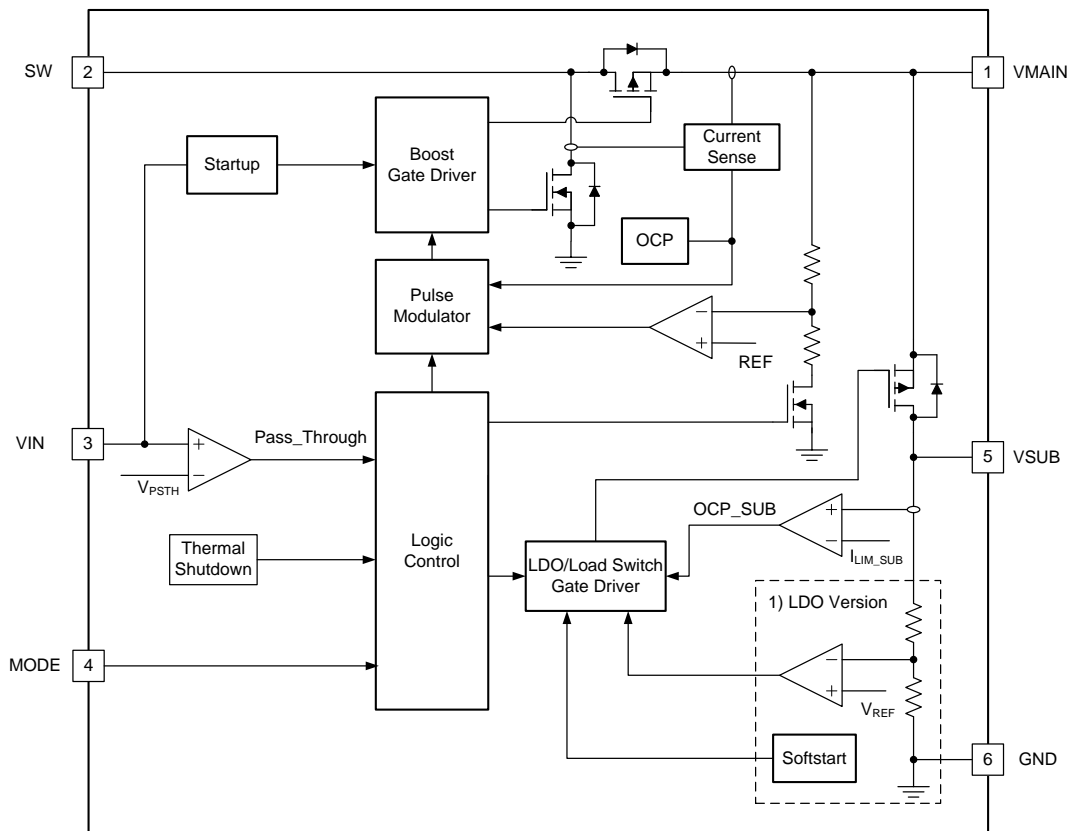
8.1 Overview

The TPS61098x is an ultra low power solution optimized for products powered by either a one-cell or two-cell alkaline, NiCd or NiMH, one-cell coin cell battery or one-cell Li-Ion or Li-polymer battery. To simplify system design and save PCB space, the TPS61098x integrates an LDO or load switch with a boost converter (different configurations for different versions) to provide two output rails in a compact package. The boost output $V_{(MAIN)}$ is designed as an always-on supply to power a main system, and the LDO or load switch output $V_{(SUB)}$ is designed to power peripheral devices and can be turned off.

The TPS61098x features two modes controlled by MODE pin: Active mode and Low Power mode. In Active mode, both outputs are enabled, and the transient response performance of the boost converter and LDO/load switch are enhanced, so it is able to respond load transient quickly. In Low Power mode, the LDO/load switch is disabled, so the peripherals can be disconnected to minimize the battery drain. Besides that, the boost consumes only 300 nA quiescent current in Low Power mode, so up to 88% efficiency at 10 μ A load can be achieved to extend the battery run time. The TPS610982 is an exception. Its LDO is always on in both Active mode and Low Power mode. The main differences between the two modes of the TPS610982 are the quiescent current and performance. Refer to [Operation Modes by MODE Pin](#) for details.

The TPS61098x supports automatic pass-through function in both Active mode and Low Power mode. When V_{IN} is detected higher than a pass-through threshold, which is around the target $V_{(MAIN)}$ voltage, the boost converter stops switching and passes the input voltage through inductor and internal rectifier switch to $V_{(MAIN)}$, so $V_{(MAIN)}$ follows V_{IN} ; when V_{IN} is lower than the threshold, the boost works in boost mode and regulates $V_{(MAIN)}$ at the target value. The TPS61098x can support different $V_{(MAIN)}$ target values in Active mode and Low Power mode to meet various requirements. For example, for TPS61098, the set value of $V_{(MAIN)}$ is 4.3 V in Active mode but 2.2 V in Low Power mode.

8.2 Functional Block Diagrams



(1) Implemented in versions with LDO configuration.

8.3 Feature Description

8.3.1 Boost Controller Operation

The TPS61098x boost converter is controlled by a hysteretic current mode controller. This controller regulates the output voltage by keeping the inductor ripple current constant in the range of 100 mA and adjusting the offset of this inductor current depending on the output load. Since the input voltage, output voltage and inductor value all affect the rising and falling slopes of inductor ripple current, the switching frequency is not fixed and is decided by the operation condition. If the required average input current is lower than the average inductor current defined by this constant ripple, the inductor current goes discontinuous to keep the efficiency high under light load conditions. 图 39 illustrates the hysteretic current operation. If the load is reduced further, the boost converter enters into Burst mode. In Burst mode, the boost converter ramps up the output voltage with several pulses and it stops operating once the output voltage exceeds a set threshold, and then it goes into a sleep status and consumes less quiescent current. It resumes switching when the output voltage is below the set threshold. It exits the Burst mode when the output current can no longer be supported in this mode. Refer to 图 40 for Burst mode operation details.

To achieve high efficiency, the power stage is realized as a synchronous boost topology. The output voltage $V_{(MAIN)}$ is monitored via an internal feedback network which is connected to the voltage error amplifier. To regulate the output voltage, the voltage error amplifier compares this feedback voltage to the internal voltage reference and adjusts the required offset of the inductor current accordingly.

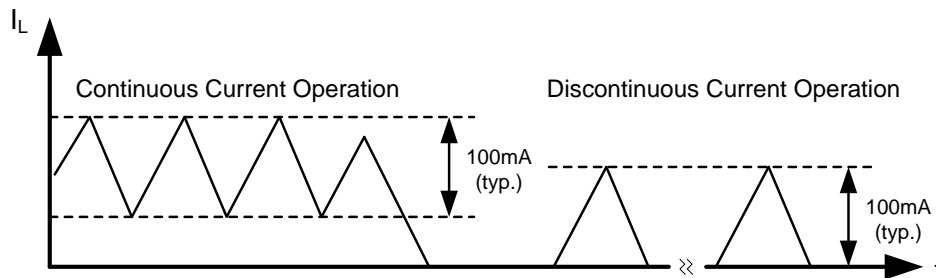


图 39. Hysteretic Current Operation

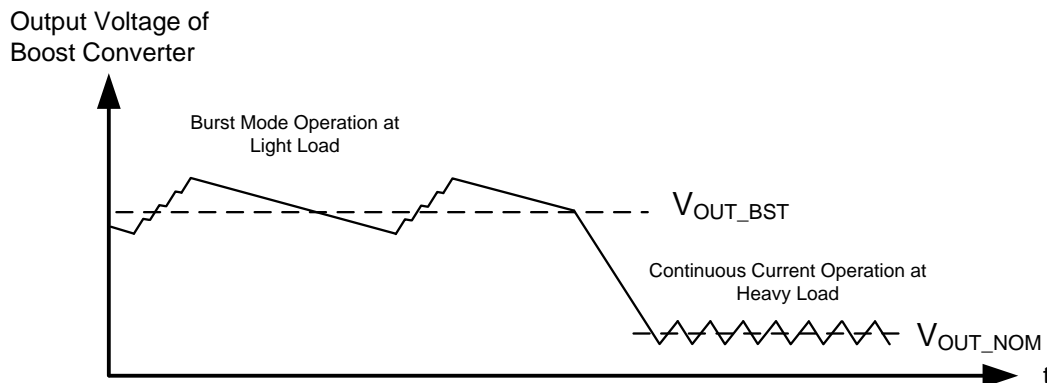


图 40. Burst Mode Operation

8.3.2 Pass-Through Operation

The TPS61098x supports automatic pass-through function for the boost converter. When the input voltage is detected higher than the pass-through threshold $V_{(PSTH)}$, which is around $V_{(MAIN)}$ set value, the boost converter enters into pass-through operation mode. In this mode, the boost converter stops switching, the rectifier is constantly turned on and the low side switch is turned off. The input voltage passes through external inductor and the internal rectifier to the output. The output voltage in this mode depends on the resistance between the input and the output, calculated as 公式 1:

$$V_{MAIN} = V_{IN} - (I_{MAIN} + I_{SUB}) \times (R_L + R_{DS(on)_HS}) \quad (1)$$

where R_L is the DCR of external inductor, and $R_{DS(on)_HS}$ is the resistance of internal rectifier.

Feature Description (接下页)

When the input voltage is lower than $V_{(PSTH)}$, the boost converter resumes switching to regulate the output at target value.

The TPS61098x can support automatic pass-through function in both Active mode and Low Power mode.

8.3.3 LDO / Load Switch Operation

The TPS61098x uses a PMOS as a pass element of its integrated LDO / load switch. The input of the PMOS is connected to the output of the boost converter. When the MODE pin is pulled logic high, the PMOS is enabled to output a voltage on VSUB pin.

For load switch version, the PMOS pass element is fully turned on when enabled, no matter the boost converter works in boost operation mode or pass-through operation mode. So the output voltage at VSUB pin is decided by the output voltage at VMAIN pin and the current passing through the PMOS as [公式 2](#):

$$V_{SUB} = V_{MAIN} - I_{SUB} \times R_{LS} \quad (2)$$

where $I_{(SUB)}$ is the load of VSUB rail and the R_{LS} is the resistance of the PMOS when it is fully turned on.

For LDO version, the output voltage $V_{(SUB)}$ is regulated at the set value when the voltage difference between its input and output is higher than the dropout voltage $V_{(Dropout)}$, no matter the boost converter works in boost operation mode or pass-through operation mode. The $V_{(SUB)}$ is monitored via an internal feedback network which is connected to the voltage error amplifier. To regulate $V_{(SUB)}$, the voltage error amplifier compares the feedback voltage to the internal voltage reference and adjusts the gate voltage of the PMOS accordingly. When the voltage drop across the PMOS is lower than the dropout voltage, the PMOS will be fully turned on and the output voltage at $V_{(SUB)}$ is decided by [公式 2](#).

When the MODE pin is pulled low, the LDO or load switch is turned off to disconnect the load at VSUB pin. For some versions, active discharge function at VSUB pin is offered, which can discharge the $V_{(SUB)}$ to ground after MODE pin is pulled low, to avoid any bias condition to downstream devices. For versions without the active discharge function, the VSUB pin is floating after MODE pin is pulled low, and its voltage normally drops down slowly due to leakage. Refer to the [Device Comparison Table](#) for version differences.

When MODE pin is toggled from low to high, soft-start is implemented for the LDO versions to avoid inrush current during LDO startup. The start up time of LDO is typically 1 ms. For load switch versions, the load switch is turned on faster, so the output capacitor at VSUB pin is suggested 10X smaller than the output capacitor at VMAIN pin to avoid obvious voltage drop of $V_{(MAIN)}$ during load switch turning on process.

8.3.4 Start Up and Power Down

The boost converter of the TPS61098x is designed always-on, so there is no enable or disable control of it. The boost converter starts operation once input voltage is applied. If the input voltage is not high enough, a low voltage startup oscillator operates the switches first. During this phase, the switching frequency is controlled by the oscillator, and the maximum switch current is limited. Once the converter has built up the output voltage $V_{(MAIN)}$ to approximately 1.8 V, the device switches to the normal hysteretic current mode operation and the VMAIN rail starts to supply the internal control circuit. If the input voltage is too low or the load during startup is too heavy, which makes the converter unable to build up 1.8 V at $V_{(MAIN)}$ rail, the boost converter can't start up successfully. It will keep in this status until the input voltage is increased or removed.

The TPS61098x is able to startup with 0.7 V input voltage with ≥ 3 k Ω load. The startup time depends on input voltage and load conditions. After the $V_{(MAIN)}$ reaches 1.8 V to start the normal hysteretic current mode operation, an internal ramp-up reference controls soft-start time of the boost converter until $V_{(MAIN)}$ reaches its set value.

The TPS61098x does not support undervoltage lockout function. When the input voltage drops to a low voltage and can't provide the required energy to the boost converter, the $V_{(MAIN)}$ drops. When and to what extent $V_{(MAIN)}$ drops are dependent on the input and load conditions. When the boost converter is unable to maintain 1.8 V at VMAIN rail to supply the internal circuit, the TPS61098x powers down and enters into startup process again.

Feature Description (接下页)

8.3.5 Over Load Protection

The boost converter of the TPS61098x supports a cycle-by-cycle current limit function in boost mode operation. If the peak inductor current reaches the internal switch current limit threshold, the main switch is turned off to stop a further increase of the input current. In this case the output voltage will decrease since the device cannot provide sufficient power to maintain the set output voltage. If the output voltage drops below the input voltage, the backgate diode of the rectifying switch gets forward biased and current starts to flow through it. Because this diode cannot be turned off, the load current is only limited by the remaining DC resistance. After the overload condition is removed, the converter automatically resumes normal operation.

The overload protection is not active in pass-through mode operation, in which the load current is only limited by the DC resistance.

The integrated LDO / load switch also supports over load protection. When the load current of VSUB rail reaches the I_{LIM_SUB} , the $V_{(SUB)}$ output current will be regulated at this limit value and will not increase further. In this case the $V_{(SUB)}$ voltage will decrease since the device cannot provide sufficient power to the load.

8.3.6 Thermal Shutdown

The TPS61098x has a built-in temperature sensor which monitors the internal junction temperature in boost mode operation. If the junction temperature exceeds the threshold (150°C typical), the device stops operating. As soon as the junction temperature has decreased below the programmed threshold with a hysteresis, it starts operating again. There is a built-in hysteresis (25°C typical) to avoid unstable operation at the overtemperature threshold. The over temperature protection is not active in pass-through mode operation.

8.4 Device Functional Modes

8.4.1 Operation Modes by MODE Pin

The TPS61098x features two operation modes controlled by MODE pin: the Active mode and Low Power mode. It can provide quick transient response in Active mode and ultra-low quiescent current in Low Power mode. So a low power system can easily use the TPS61098x to get high performance in its active mode and meantime minimize its power consumption to extend the battery run time in its sleep mode.

The MODE pin is usually controlled by an I/O pin of a controller, and should not be left floating.

8.4.1.1 Active Mode

The TPS61098x works in Active mode when MODE pin is logic high. In Active mode, both of the boost converter and the integrated LDO/load switch are enabled, and the TPS61098x can provide dual outputs simultaneously. The transient response performance of the boost converter is enhanced in Active mode, and the device consumes around 15 μ A quiescent current. It is able to respond load transient quickly.

When MODE pin is toggled from low to high, soft-start is implemented for the LDO versions to avoid inrush current during startup. For load switch versions, the load switch is turned on faster, so the output capacitor at VSUB pin is suggested 10X smaller than the output capacitor at VMAIN pin to avoid obvious voltage drop of $V_{(MAIN)}$ during turning on process.

8.4.1.2 Low Power Mode

The TPS61098x works in Low Power mode when MODE pin is logic low. In Low Power mode, the LDO/load switch is turned off, so the peripherals can be disconnected to minimize the battery drain. The VSUB pin either outputs high impedance or is pulled to ground by internal active discharge circuit, depending on different versions. The boost converter consumes only 300 nA quiescent current typically, and can achieve up to 88% efficiency at 10 μ A load.

The Low Power mode is designed to keep the load device powered with minimum power consumption. For example, it can be used to keep powering the main system, like an MCU, in a system's sleep mode even under < 0.7 V input voltage condition.

图 41 和 图 42 illustrate the outputs of the TPS61098 and TPS610981 under different input voltages in Active mode and Low Power mode.

Device Functional Modes (接下页)

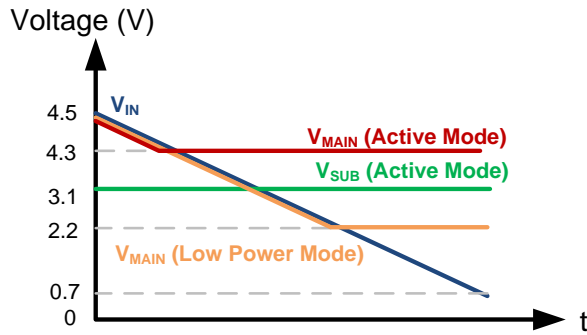


图 41. TPS61098 Output under Different Input Voltages

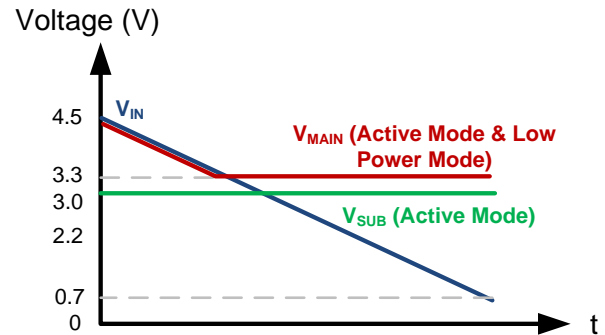


图 42. TPS610981 Output under Different Input Voltages

The TPS610982 is an exception. Its LDO is always on in both Active mode and Low Power mode with higher quiescent current consumption than other versions. The TPS610982 can be used to replace discrete boost and LDO solutions where the LDO output is always on, and its two modes provide users two options of different quiescent current consumption and performance. Refer to the [Device Comparison Table](#), [Specifications](#) and [Typical Characteristics](#) for details.

8.4.2 Burst Mode Operation under Light Load Condition

The boost converter of TPS61098x enters into Burst Mode operation under light load condition. Refer to [Boost Controller Operation](#) for details.

8.4.3 Pass-Through Mode Operation

The boost converter of TPS61098x automatically enters into pass-through mode operation when input voltage is higher than the target output voltage. Refer to [Pass-Through Operation](#) for details.

9 Applications and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS61098x is an ultra low power solution for products powered by either a one-cell or two-cell alkaline, NiCd or NiMH, one-cell coin cell or one-cell Li-Ion or Li-polymer battery. It integrates either a Low-dropout Linear Regulator (LDO) or a load switch with a boost converter and provides dual output rails. The $V_{(MAIN)}$ rail is the output of the boost converter. It is an always-on output and can only be turned off by removing input voltage. The $V_{(SUB)}$ rail is the output of the integrated LDO or load switch, and it can be turned off by pulling the MODE pin low.

9.2 Typical Applications

9.2.1 VMAIN to Power MCU and VSUB to Power Subsystem

The TPS61098x suits for low power systems very well, especially for the system which spends the most of time in sleep mode and wakes up periodically to sense or transmit signals. For this kind of application, the boost output $V_{(MAIN)}$ can be used as an always-on supply for the main system, such as an MCU controller, and the LDO or load switch output $V_{(SUB)}$ is used to power peripheral devices or subsystem.

As shown in 图 43, the MCU can control both of the subsystem and the TPS61098x. When the system goes into sleep mode, the MCU can disable the subsystem first, and then force the TPS61098x enter into Low Power mode, where the $V_{(SUB)}$ rail is disconnected but the $V_{(MAIN)}$ rail still powers the MCU with only 300 nA quiescent current. When the system wakes up, the MCU pulls the MODE pin of TPS61098x high first to turn on the $V_{(SUB)}$ rail, and then enables the subsystem. In this way, the system can benefit both of the enhanced transient response performance in active mode and the ultra-low quiescent current in sleep mode.

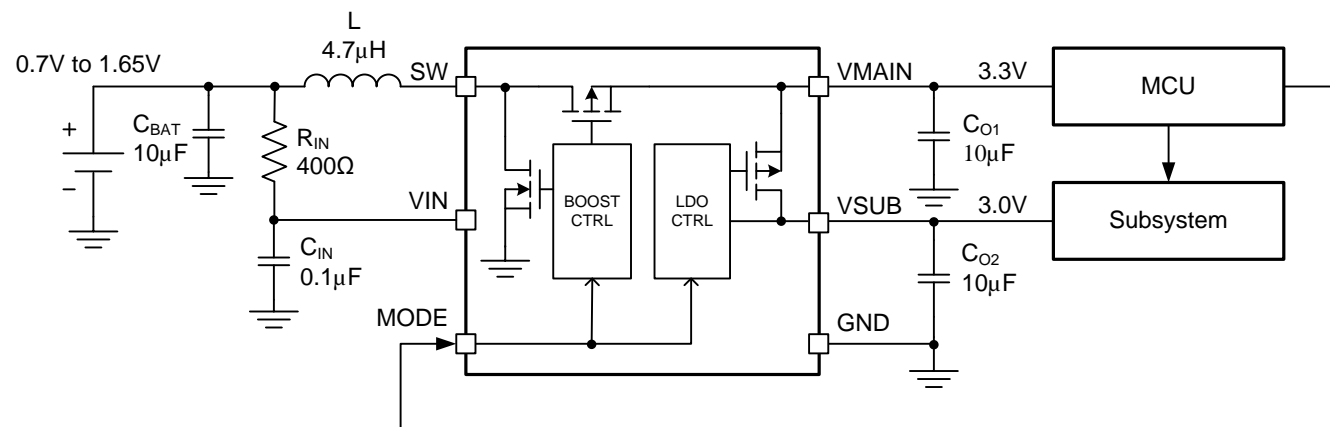


图 43. Typical Application of TPS610981 to Power Low Power System

9.2.1.1 Design Requirements

- 3.3 V $V_{(MAIN)}$ rail to power MCU with 15 mA load current, 3 V $V_{(SUB)}$ rail to power subsystem with 10 mA load current
- Power source, single-cell alkaline battery (0.7 V to 1.65 V range)
- Greater than 90% conversion efficiency

Typical Applications (接下页)

9.2.1.2 Detailed Design Procedure

9.2.1.2.1 Device Choice

In the TPS61098x family, different versions are provided. Refer to [Device Comparison Table](#) for version details and select the right version for target applications. It is OK to use only one output rail, either $V_{(MAIN)}$ or $V_{(BUS)}$, as long as it suits the application.

In this example, dual rails of 3.3 V and 3 V are required to power both MCU and subsystem, so the TPS610981 is selected.

9.2.1.2.2 Maximum Output Current

For the boost converter, it provides output current for both $V_{(MAIN)}$ and $V_{(SUB)}$ rails. Its maximum output capability is determined by the input to output ratio and the current limit of the boost converter and can be estimated by [公式 3](#).

$$I_{OUT(max)} = \frac{V_{IN} \times (I_{LIM_BST} - 50mA) \times \eta}{V_{MAIN}} \quad (3)$$

where η is the boost converter power efficiency estimation, and 50 mA is half of the inductor current ripple value. Minimum input voltage, maximum boost output voltage and minimum current limit I_{LIM_BST} should be used as the worst case condition for the estimation.

Internal current limit is also implemented for the integrated LDO/load switch. So the maximum output current of V_{SUB} rail should be lower than I_{LIM_SUB} , which has 200 mA minimum value. For LDO version, the maximum output current is also limited by its input to output headroom, that is $V_{(MAIN)} - V_{(SUB)}$. Make sure the headroom voltage is enough to support the load current. Please refer to [Electrical Characteristics](#) for the dropout voltage information.

In this example, assume the power efficiency is 80% (lower than typical value for the worst case estimation), so the calculated maximum output current of the boost converter is 50.9 mA, which satisfies the application requirements (15 mA + 10 mA). The load of V_{SUB} rail is 10 mA, which is well below the $V_{(SUB)}$ rail current limit and the dropout voltage is also within the headroom.

9.2.1.2.3 Inductor Selection

Because the selection of the inductor affects steady state operation, transient behavior, and loop stability, the inductor is the most important component in power regulator design. There are three important inductor specifications, inductor value, saturation current, and dc resistance (DCR).

The TPS61098x is designed to work with inductor values between 2.2 μ H and 4.7 μ H. The inductance values affects the switching frequency f in continuous current operation, which is proportional to $1/L$ as shown in [公式 4](#).

$$f = \frac{1}{L \times 100mA} \times \frac{V_{IN} \times (V_{MAIN} - V_{IN} \times \eta)}{V_{MAIN}} \quad (4)$$

The inductor current ripple is fixed to 100mA typical value by internal design, but it can be affected by the inductor value indirectly. Normally when a smaller inductor value is applied, the inductor current ramps up and down more quickly, so the current ripple becomes bigger because the internal current comparator has some delay to respond. So if smaller inductor peak current is required in applications, a higher inductor value can be tried. However, the TPS61098x is optimized to work within a range of L and C combinations. The LC output filter inductance and capacitance must be considered together. The output capacitor sets the corner frequency of the converter while the inductor creates a Right-Half-Plane-Zero degrading the stability of the converter. Consequently with a larger inductor, a bigger capacitor normally should be used to ensure the same L/C ratio thus a stable loop.

Having selected an inductance value, the peak current for the inductor in steady-state operation varies as a function of the load, the input and output voltages and can be estimated using [公式 5](#).

$$I_{L,MAX} = \frac{V_{MAIN} \times (I_{MAIN} + I_{SUB})}{V_{IN} \times \eta} + 50mA; \text{ continuous current operation}$$

$$I_{L,MAX} = 100mA; \text{ discontinuous current operation} \quad (5)$$

Typical Applications (接下页)

where, 80% can be used for the boost converter power efficiency estimation, 100 mA is the typical inductor current ripple value and 50mA is half of the ripple value, which may be affected a little bit by inductor value. [公式 5](#) provides a suitable inductor current rating by using minimum input voltage, maximum boost output voltage and maximum load current for the calculation. Load transients and error conditions may cause higher inductor currents.

[公式 6](#) provides an easy way to estimate whether the device will work in continuous or discontinuous operation depending on the operating points. As long as the [公式 6](#) is true, continuous operation is typically established. If [公式 6](#) becomes false, discontinuous operation is typically established.

$$\frac{V_{\text{MAIN}} \times (I_{\text{MAIN}} + I_{\text{SUB}})}{V_{\text{IN}} \times \eta} > 50\text{mA} \tag{6}$$

Selecting an inductor with insufficient saturation performance can lead to excessive peak current in the converter. This could eventually harm the device and reduce its reliability.

In this example, the maximum load for the boost converter is 25 mA, and the minimum input voltage is 0.7 V, and the efficiency under this condition can be estimated at 80%, so the boost converter works in continuous operation by the calculation. The inductor peak current is calculated as 197 mA. To leave some margin, a 4.7 μH inductor with at least 250 mA saturation current is recommended for this application.

[表 1](#) also lists the recommended inductor for the TPS61098x device.

表 1. List of Inductors

INDUCTANCE [μH]	ISAT [A]	IRMS [A]	DC RESISTANCE [mΩ]	PART NUMBER	MANUFACTURER
4.7	0.86	1.08	168	VLF302510MT-4R7M	TDK
4.7	0.57	0.95	300	VLF252010MT-4R7M	TDK
2.2	1.23	1.5	84	VLF302510MT-2R2M	TDK
2.2	0.83	0.92	120	VLF252010MT-2R2M	TDK

9.2.1.2.4 Capacitor Selection

For best output and input voltage filtering, low ESR X5R or X7R ceramic capacitors are recommended.

The input capacitor minimizes input voltage ripple, suppresses input voltage spikes and provides a stable system rail for the device. An input capacitor value of at least 10 μF is recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. A ceramic capacitor placed as close as possible to the VIN and GND pins of the IC is recommended. For applications where line transient is expected, an input filter composed of 400-Ω resistor and 0.1-μF capacitor as shown in [图 43](#) is mandatory to avoid interference to internal pass-through threshold comparison circuitry.

For the output capacitor of VMAIN pin, small ceramic capacitors are recommended, placed as close as possible to the VMAIN and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which cannot be placed close to the IC, the use of a small ceramic capacitor with a capacitance value of around 2.2 μF in parallel to the large one is recommended. This small capacitor should be placed as close as possible to the VMAIN and GND pins of the IC. The recommended typical output capacitor values are 10 μF and 22 μF (nominal values).

For LDO version, like all low dropout regulators, VSUB rail requires an output capacitor connected between VSUB and GND pins to stabilize the internal control loop. Ceramic capacitor of 10 μF (nominal value) is recommended for most applications. If the V_(SUB) drop during load transient is much cared, higher capacitance value up to 22 μF is recommended to provide better load transient performance. Capacitor below 10 μF is only recommended for light load operation. For load switch version, capacitor of 10x smaller value than capacitor at VMAIN pin is recommended to minimize the voltage drop caused by charge sharing when the load switch is turned on.

When selecting capacitors, ceramic capacitor's derating effect under bias should be considered. Choose the right nominal capacitance by checking capacitor's DC bias characteristics. In this example, GRM188R60J106ME84D, which is a 10 μF ceramic capacitor with high effective capacitance value at DC biased condition, is selected for both VMAIN and VSUB rails. The load transient response performance is shown in [Application Curves](#) section.

9.2.1.2.5 Control Sequence

In this example, the MCU is powered by the boost output $V_{(MAIN)}$ and the subsystem is powered by the LDO $V_{(SUB)}$. MCU controls both of the TPS610981 and subsystem. The control sequence as shown in 图 44 is recommended.

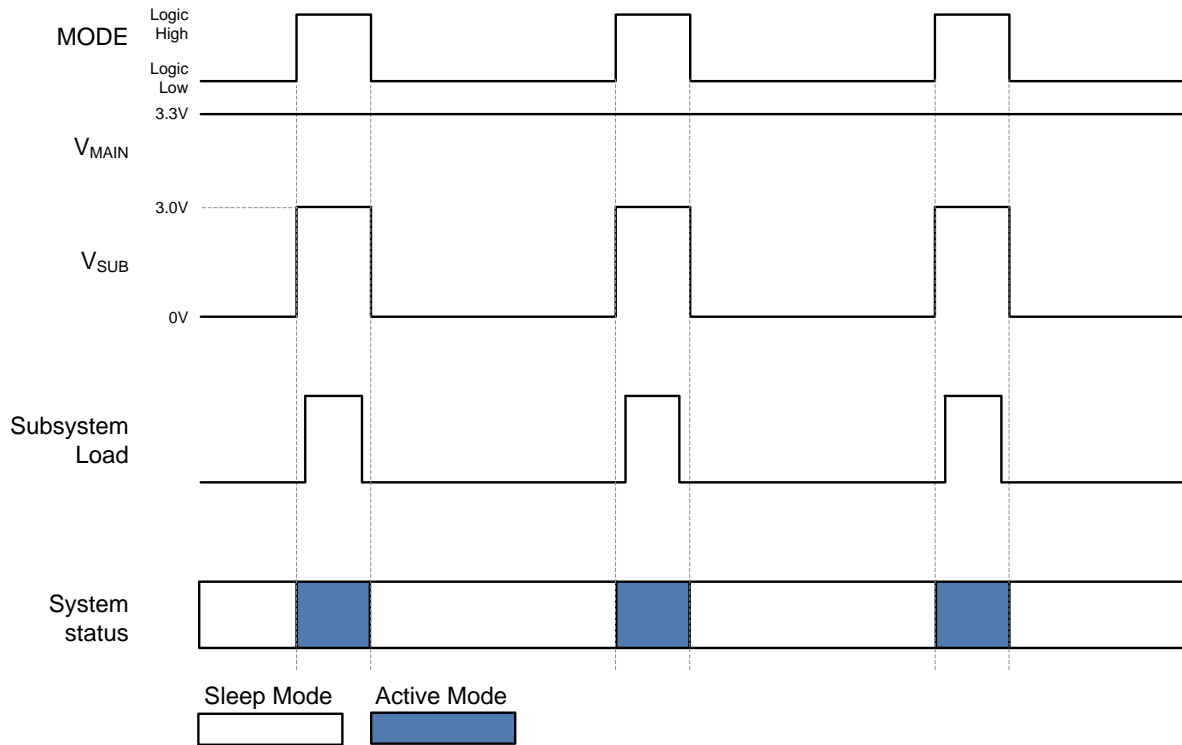
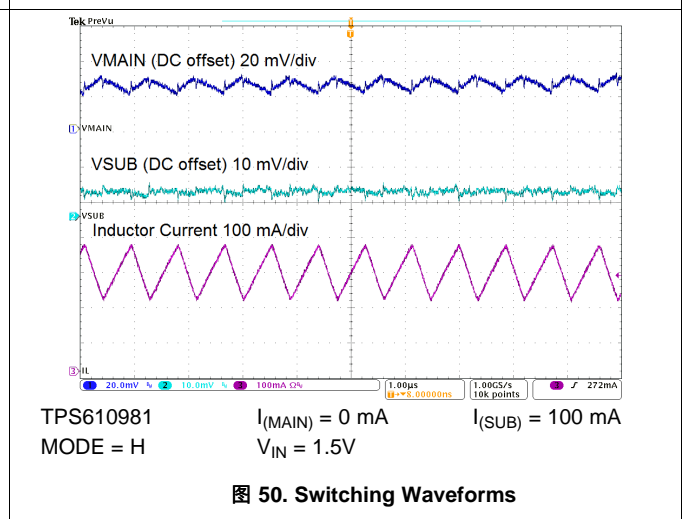
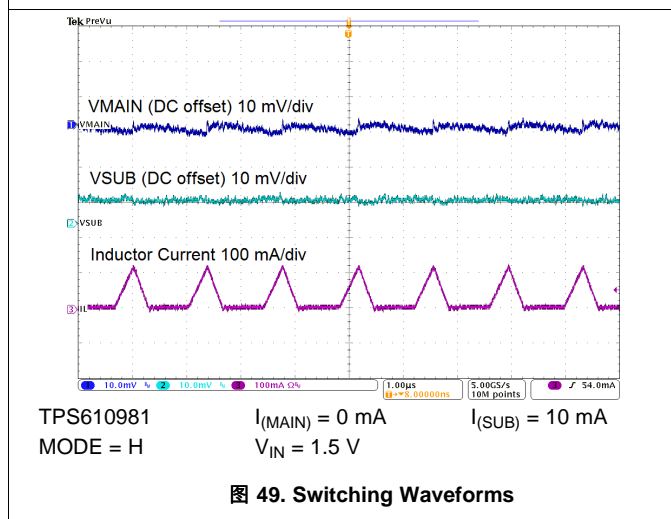
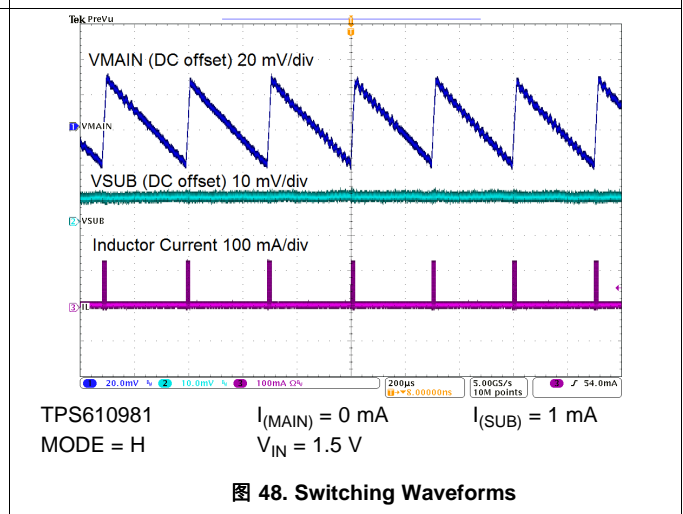
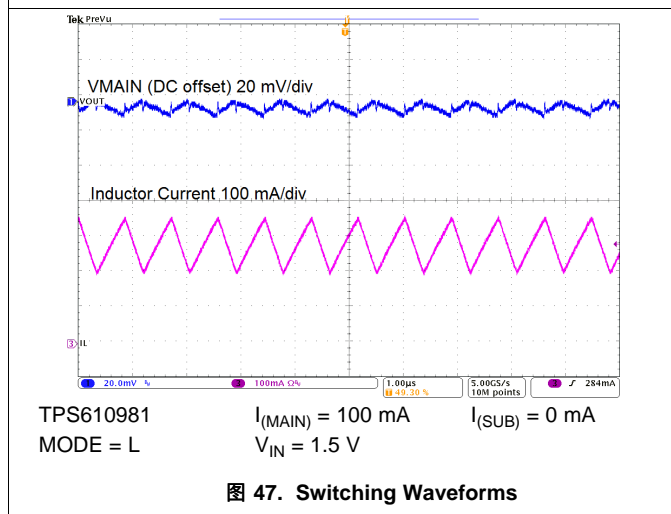
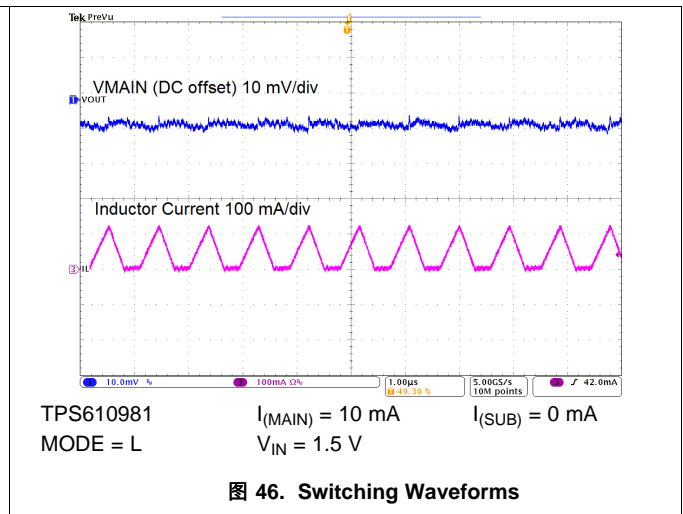
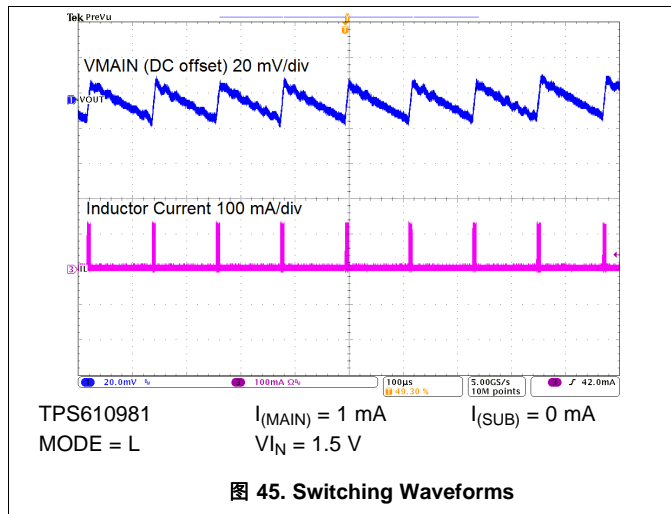


图 44. System Control Sequence

When the system is waking up, the MCU wakes up itself first, and it then pulls the MODE pin of TPS610981 to high to turn on the $V_{(SUB)}$ rail. TPS610981 enters into Active mode and gets ready to provide power to the subsystem. Then the MCU enables the subsystem.

When the system is entering into sleep mode, the MCU disables the subsystem first and then pulls the MODE pin to low to turn off the $V_{(SUB)}$, so the subsystem is disconnected from the supply to minimize the current drain. TPS610981 enters into Low Power mode and the V_{MAIN} rail still powers the MCU with only 300 nA quiescent current. The MCU enters into sleep mode itself finally.

9.2.1.3 Application Curves



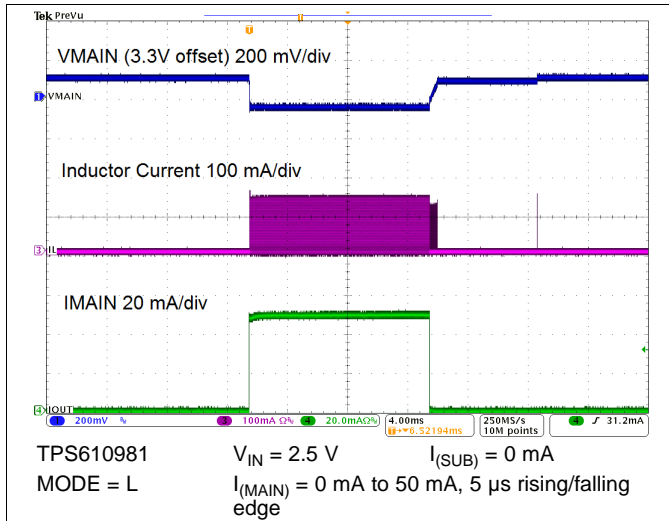


图 51. Load Transient Response

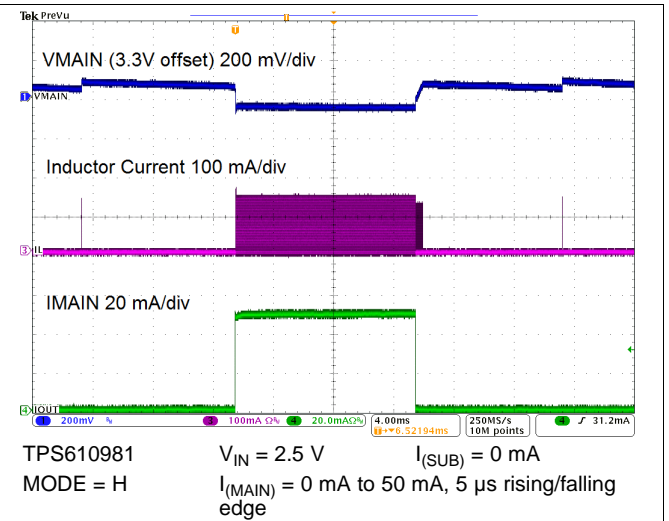


图 52. Load Transient Response

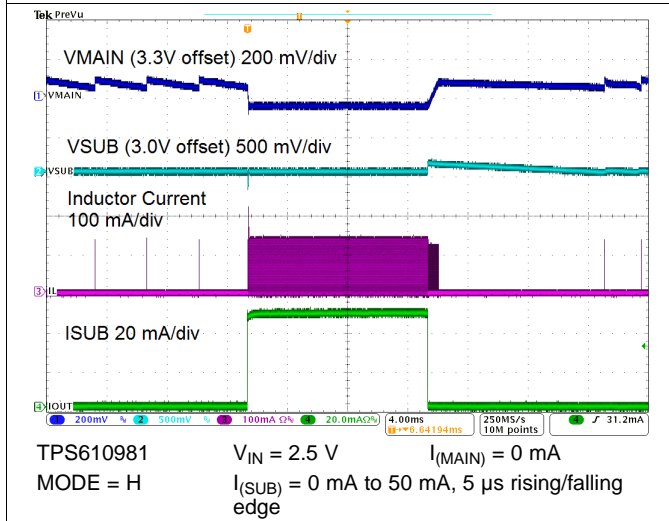


图 53. LDO Load Transient Response

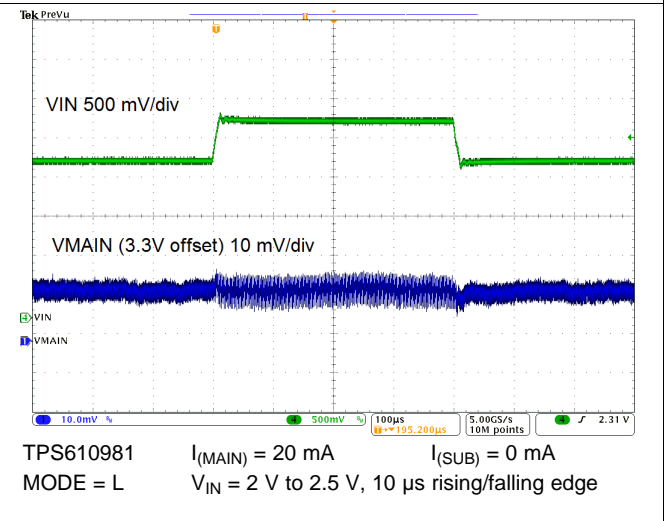


图 54. Line Transient Response

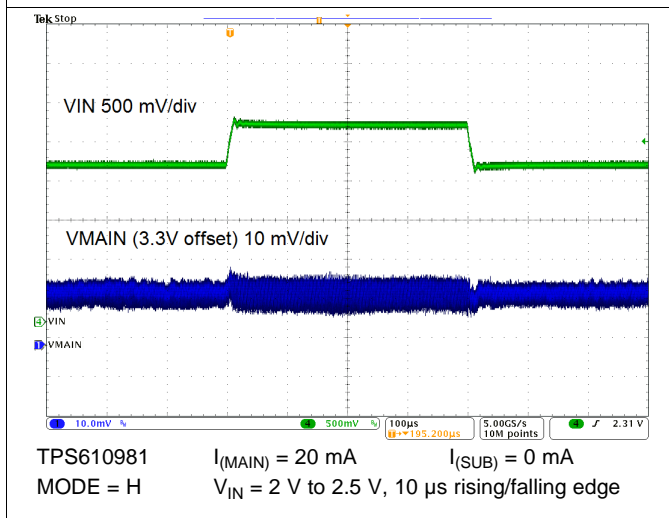


图 55. Line Transient Response

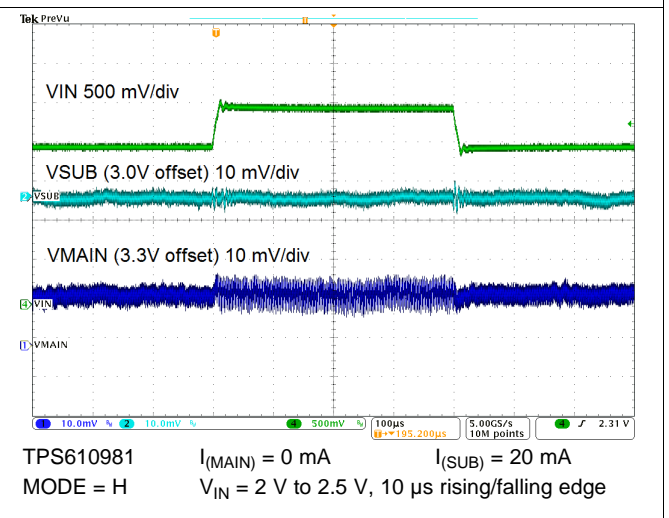
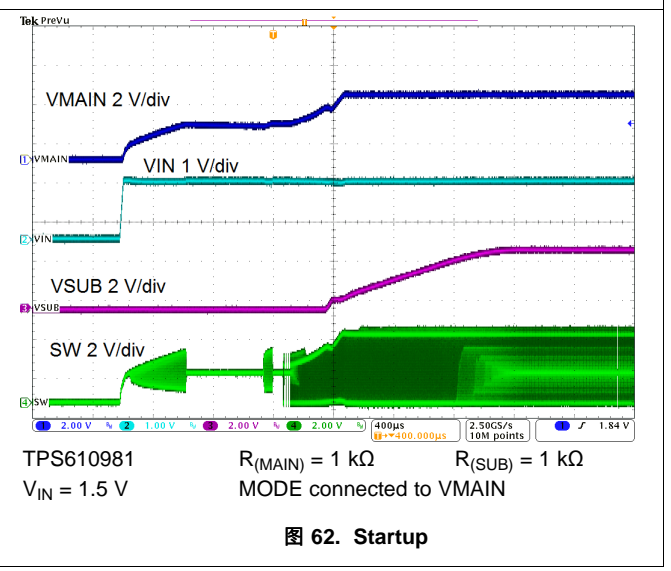
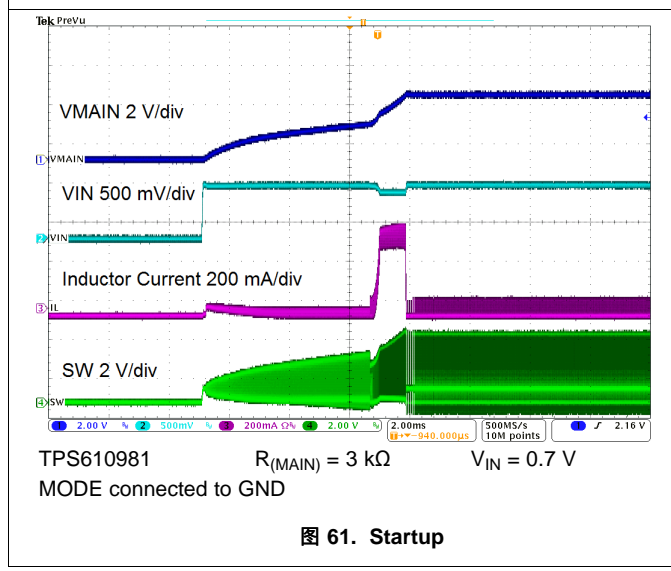
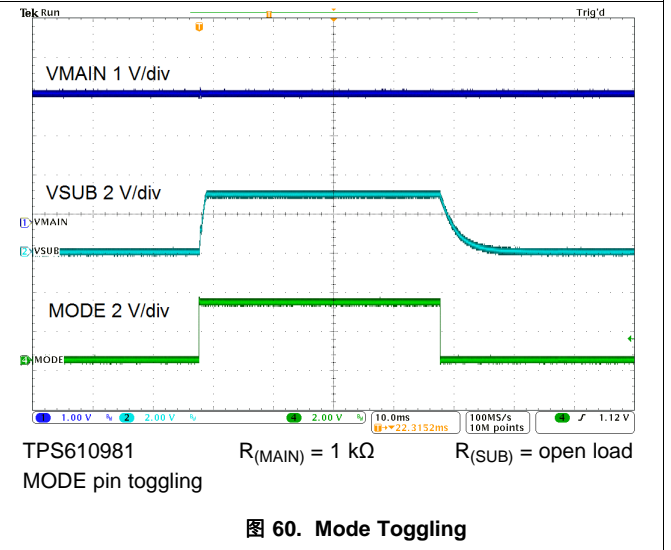
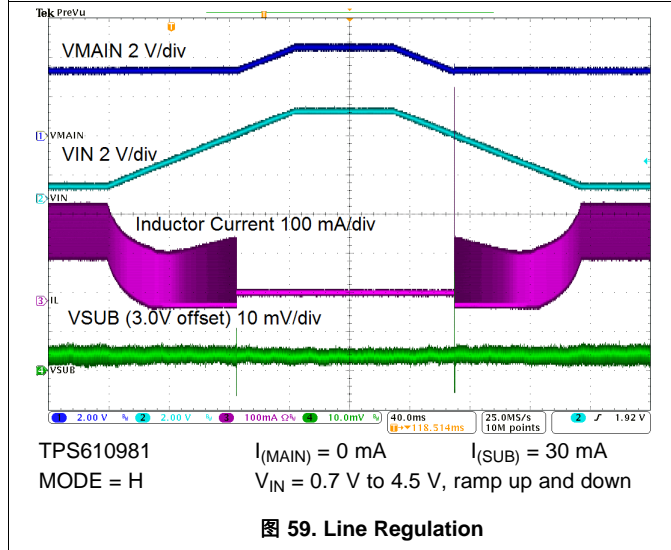
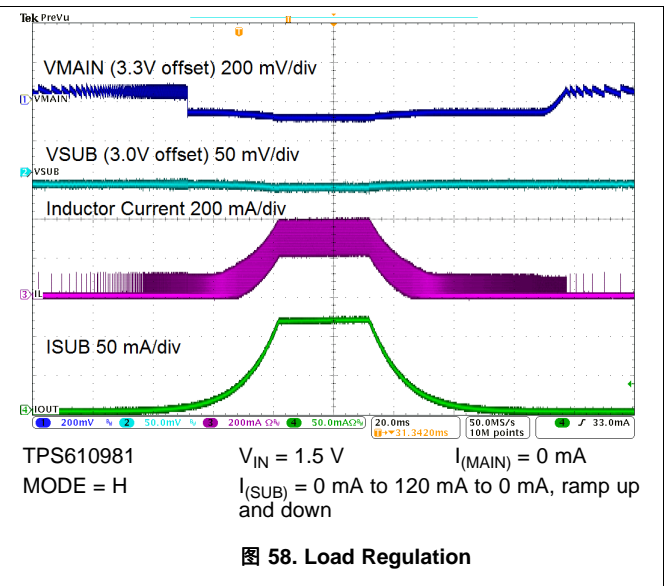
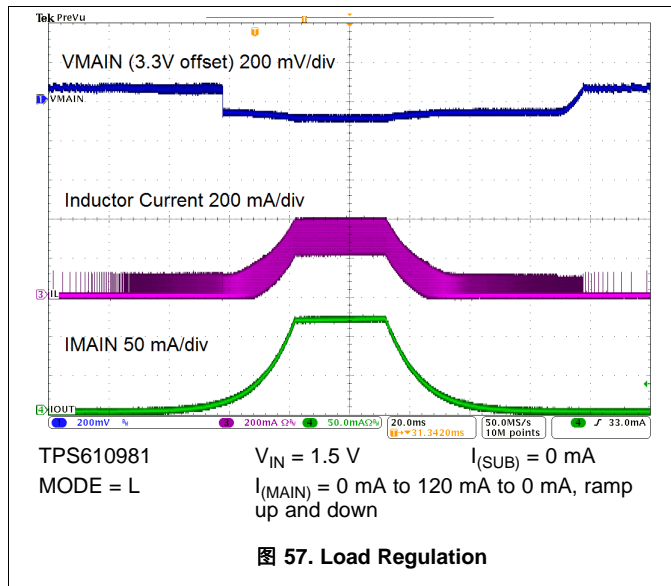


图 56. Line Transient Response



9.2.2 VMAIN to Power the System in Low Power Mode

If only one power supply is needed for the whole system, users can easily leave the VSUB pin float and only use the VMAIN rail as the power supply. In this case, the TPS61098x functions as a standard boost converter. If enhanced load transient performance is needed when the system works in Active mode, the controller can control the MODE pin to switch the TPS61098x between the Active mode and Low Power mode. If the ultra-low Iq is critical for the application, users can connect the MODE pin to GND so the TPS61098x keeps working in Low Power mode with only 300 nA quiescent current. Below shows a typical application where the TPS61098 is used in Low Power mode to generate 2.2 V with only 300 nA Iq to power the whole system.

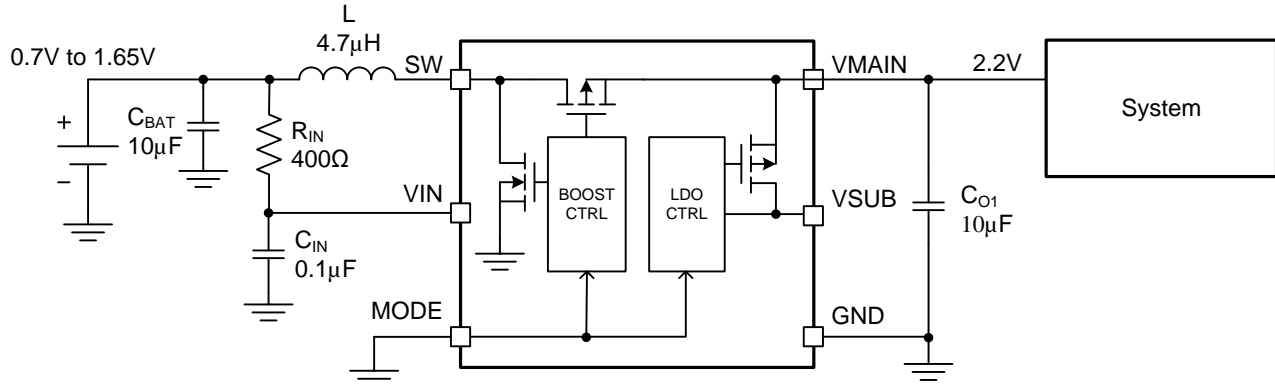


图 63. Typical Application of TPS61098 VMAIN to Power the System in Low Power Mode

9.2.2.1 Design Requirements

- 2.2 V $V_{(MAIN)}$ to power the whole system
- Power source, single-cell alkaline battery (0.7 V to 1.65 V range)
- $\geq 80\%$ conversion efficiency at 10 μ A load

9.2.2.2 Detailed Design Procedure

Refer to the [Detailed Design Procedure](#) section for the detailed design steps.

9.2.2.3 Application Curves

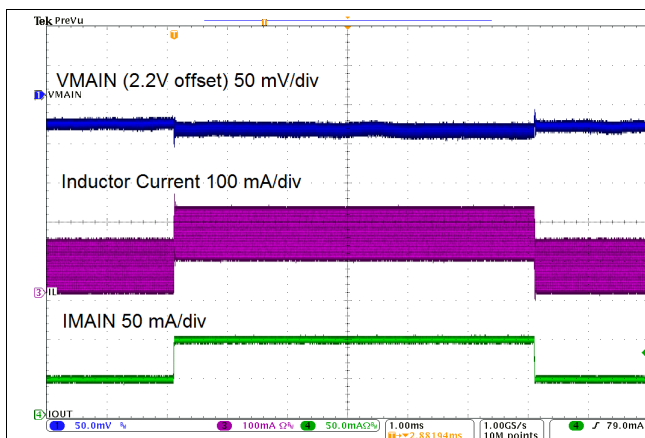


图 64. Load Transient Response

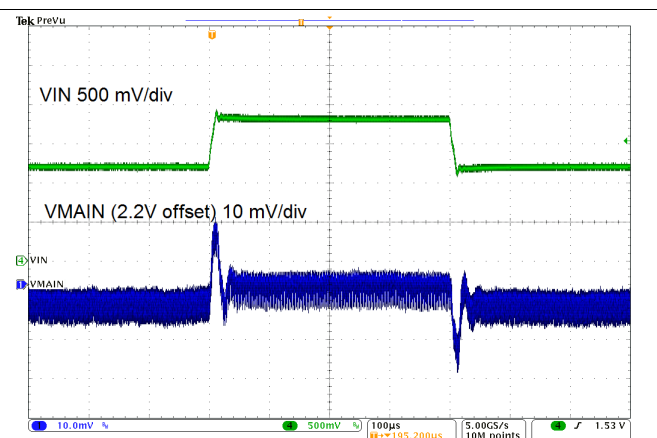
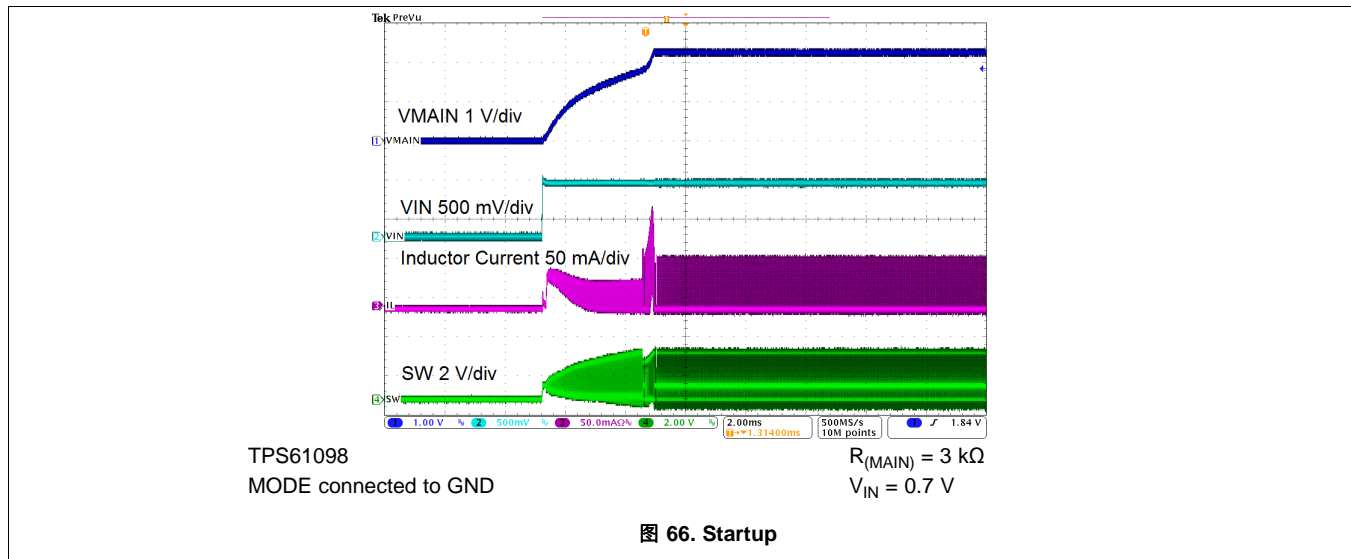


图 65. Line Transient Response



9.2.3 VSUB to Power the System in Active Mode

In some applications, the system controller can be powered by the battery directly, but a buck-boost or a boost converter with an LDO is needed to provide a quiet power supply for a subsystem like a sensor. In this type of application, the TPS61098x can be used to replace the discrete boost converter and the LDO, providing a compact solution to simplify the system design and save the PCB space. The LDO can be turned on and off by the MODE pin. When the MODE pin is pulled low, the LDO is turned off to disconnect the load, and the TPS61098x also enters into Low Power mode to save power consumption. 图 67 shows an application where the VSUB of the TPS61098 is used to supply the 3.1 V for a sensor in a system. The boost converter of the TPS61098 outputs 4.3 V and provides enough headroom for the LDO operation.

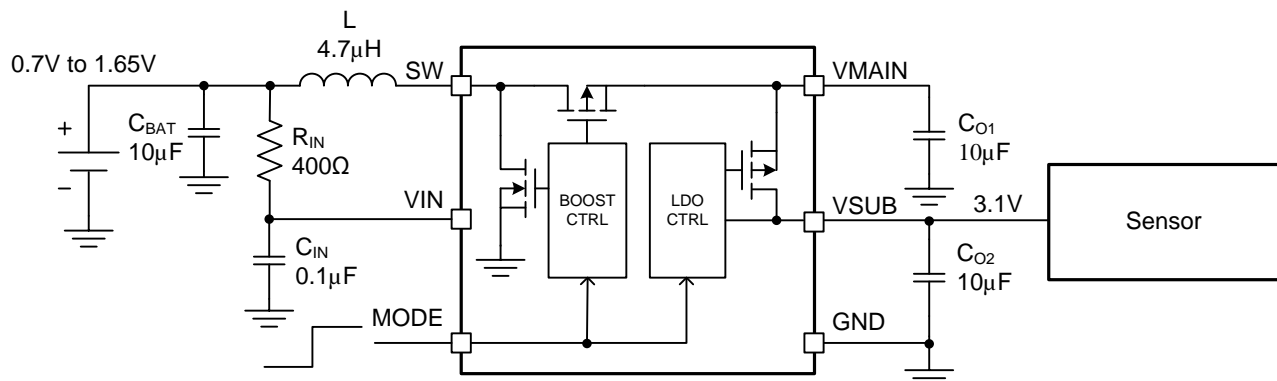


图 67. Typical Application of TPS61098 VSUB to Power the System in Active Mode

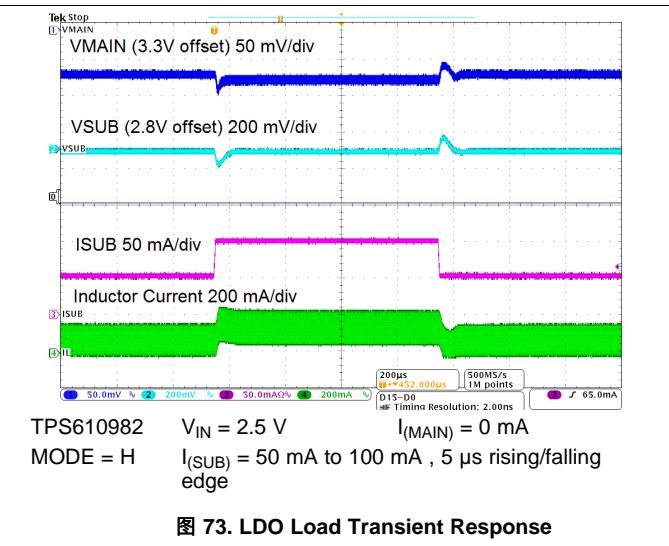
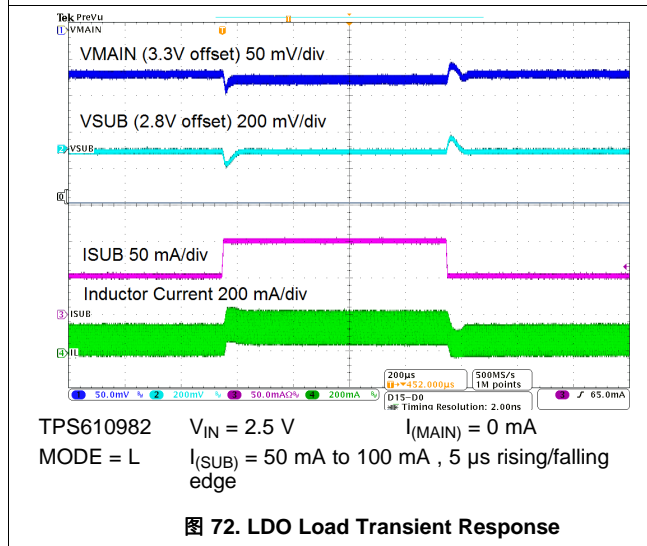
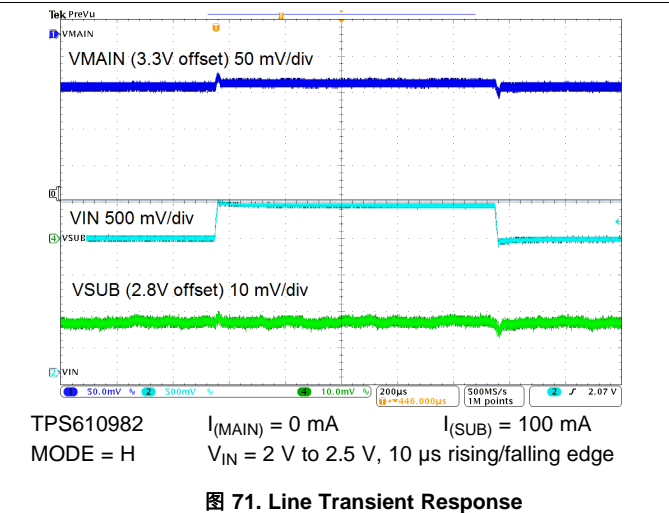
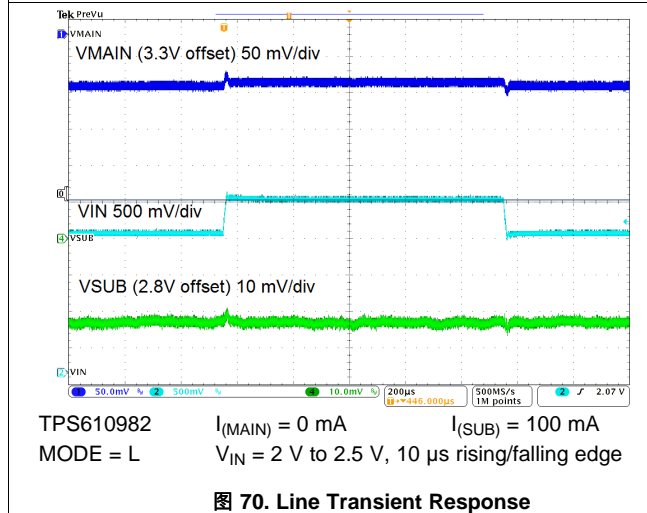
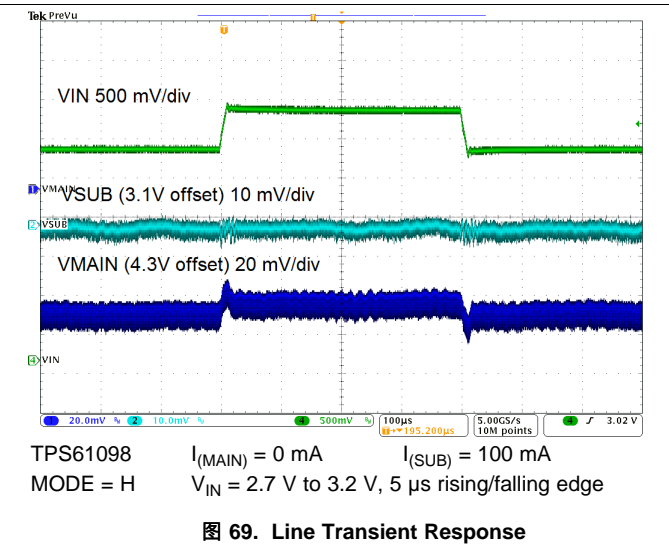
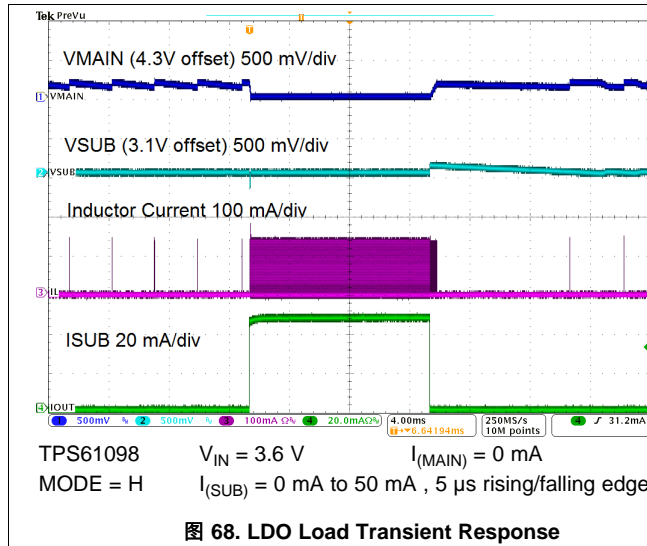
9.2.3.1 Design Requirements

- 3.1 V rail to power a sensor
- Power source, single-cell li-ion battery (2.7 V to 4.3 V range)

9.2.3.2 Detailed Design Procedure

Refer to the [Detailed Design Procedure](#) section for the detailed design steps.

9.2.3.3 Application Curves



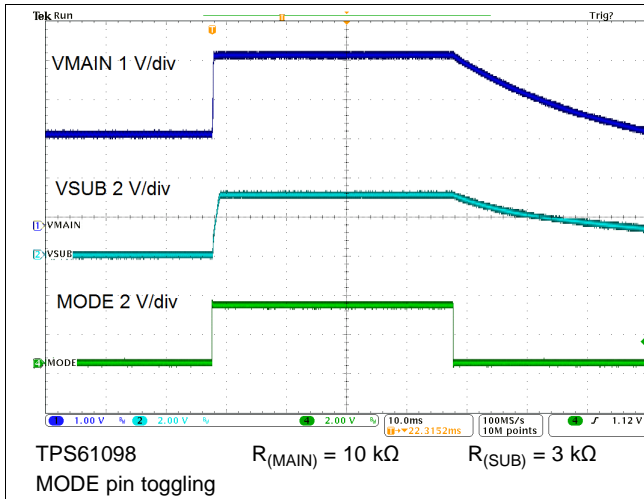


图 74. MODE Toggling

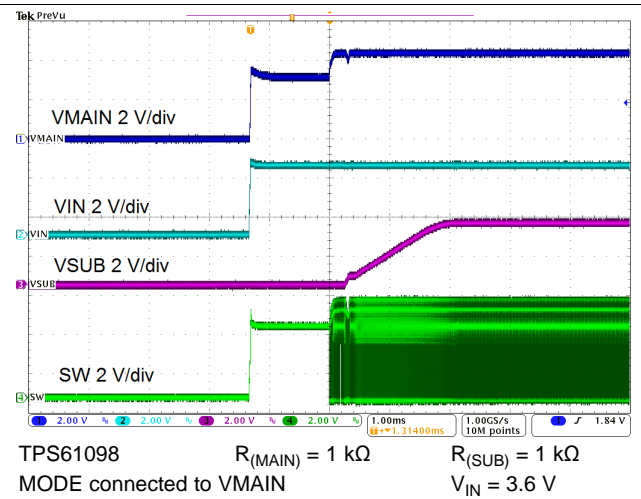


图 75. Startup

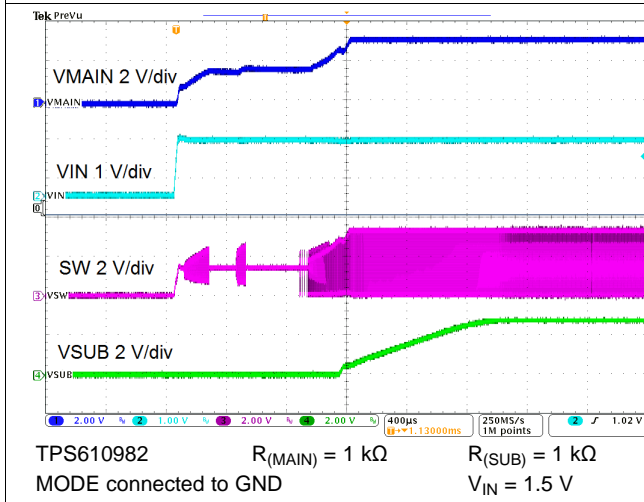


图 76. Startup

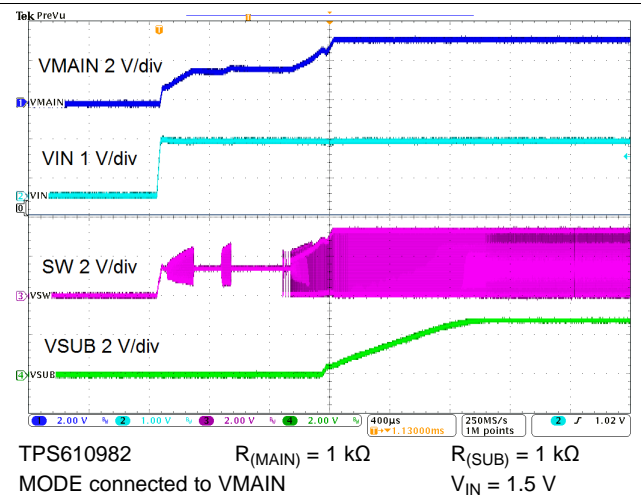


图 77. Startup

10 Power Supply Recommendations

The TPS61098x family is designed to operate from an input voltage supply range between 0.7 V to 4.5 V. The power supply can be either a one-cell or two-cell alkaline, NiCd or NiMH, one-cell coin cell or one-cell Li-Ion or Li-polymer battery. The input supply should be well regulated with the rating of TPS61098x.

11 Layout

11.1 Layout Guidelines

As for all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground paths. The input and output capacitor, as well as the inductor should be placed as close as possible to the IC.

11.2 Layout Example

The bottom layer is a large GND plane connected by vias.

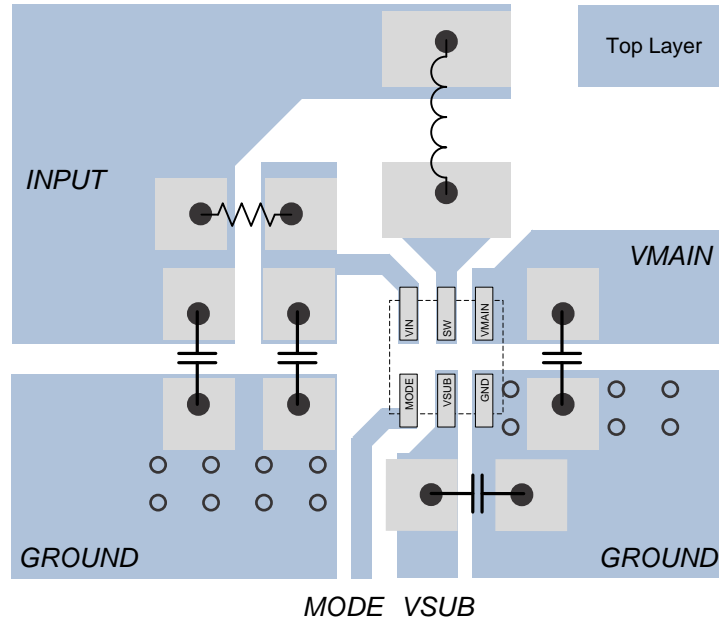


图 78. Layout

12 器件和文档支持

12.1 器件支持

12.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

12.2 文档支持

《执行精确的 PFM 模式效率测量》，[SLVA236](#)

《精确测量超低 IQ 器件的效率》，[SLYT558](#)

《IQ: 它是什么、不是什么以及如何使用》，[SLYT412](#)

12.3 相关链接

以下表格列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件，并且可以快速访问样片或购买链接。

表 2. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
TPS61098	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
TPS610981	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
TPS610982	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

12.4 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.5 商标

E2E is a trademark of Texas Instruments.

12.6 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

12.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不阅读本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

重要声明

德州仪器(TI)及其下属子公司有权根据 JESD46 最新标准,对所提供的产品和服务进行更正、修改、增强、改进或其它更改,并有权根据 JESD48 最新标准中止提供任何产品和服务。客户在下订单前应获取最新的相关信息,并验证这些信息是否完整且是最新的。所有产品的销售都遵循在订单确认时所提供的TI 销售条款与条件。

TI 保证其所销售的组件的性能符合产品销售时 TI 半导体产品销售条件与条款的适用规范。仅在 TI 保证的范围内,且 TI 认为有必要时才会使用测试或其它质量控制技术。除非适用法律做出了硬性规定,否则没有必要对每种组件的所有参数进行测试。

TI 对应用帮助或客户产品设计不承担任何义务。客户应对其使用 TI 组件的产品和应用自行负责。为尽量减小与客户产品和应用相关的风险,客户应提供充分的设计与操作安全措施。

TI 不对任何 TI 专利权、版权、屏蔽作品权或其它与使用了 TI 组件或服务的组合设备、机器或流程相关的 TI 知识产权中授予的直接或隐含权限作出任何保证或解释。TI 所发布的与第三方产品或服务有关的信息,不能构成从 TI 获得使用这些产品或服务的许可、授权、或认可。使用此类信息可能需要获得第三方的专利权或其它知识产权方面的许可,或是 TI 的专利权或其它知识产权方面的许可。

对于 TI 的产品手册或数据表中 TI 信息的重要部分,仅在没有对内容进行任何篡改且带有相关授权、条件、限制和声明的情况下才允许进行复制。TI 对此类篡改过的文件不承担任何责任或义务。复制第三方的信息可能需要服从额外的限制条件。

在转售 TI 组件或服务时,如果对该组件或服务参数的陈述与 TI 标明的参数相比存在差异或虚假成分,则会失去相关 TI 组件或服务的所有明示或暗示授权,且这是不正当的、欺诈性商业行为。TI 对任何此类虚假陈述均不承担任何责任或义务。

客户认可并同意,尽管任何应用相关信息或支持仍可能由 TI 提供,但他们将独立负责满足与其产品及其在应用中使用的 TI 产品相关的所有法律、法规和安全相关要求。客户声明并同意,他们具备制定与实施安全措施所需的全部专业技术和知识,可预见故障的危险后果、监测故障及其后果、降低有可能造成人身伤害的故障的发生机率并采取适当的补救措施。客户将全额赔偿因在此类安全关键应用中使用任何 TI 组件而对 TI 及其代理造成的任何损失。

在某些场合中,为了推进安全相关应用有可能对 TI 组件进行特别的促销。TI 的目标是利用此类组件帮助客户设计和创立其特有的可满足适用的功能安全性标准和要求的终端产品解决方案。尽管如此,此类组件仍然服从这些条款。

TI 组件未获得用于 FDA Class III (或类似的生命攸关医疗设备)的授权许可,除非各方授权官员已经达成了专门管控此类使用的特别协议。

只有那些 TI 特别注明属于军用等级或“增强型塑料”的 TI 组件才是设计或专门用于军事/航空应用或环境的。购买者认可并同意,对并非指定面向军事或航空航天用途的 TI 组件进行军事或航空航天方面的应用,其风险由客户单独承担,并且由客户独立负责满足与此类使用相关的所有法律和法规要求。

TI 已明确指定符合 ISO/TS16949 要求的产品,这些产品主要用于汽车。在任何情况下,因使用非指定产品而无法达到 ISO/TS16949 要求, TI 不承担任何责任。

	产品		应用
数字音频	www.ti.com.cn/audio	通信与电信	www.ti.com.cn/telecom
放大器和线性器件	www.ti.com.cn/amplifiers	计算机及周边	www.ti.com.cn/computer
数据转换器	www.ti.com.cn/dataconverters	消费电子	www.ti.com.cn/consumer-apps
DLP® 产品	www.dlp.com	能源	www.ti.com.cn/energy
DSP - 数字信号处理器	www.ti.com.cn/dsp	工业应用	www.ti.com.cn/industrial
时钟和计时器	www.ti.com.cn/clockandtimers	医疗电子	www.ti.com.cn/medical
接口	www.ti.com.cn/interface	安防应用	www.ti.com.cn/security
逻辑	www.ti.com.cn/logic	汽车电子	www.ti.com.cn/automotive
电源管理	www.ti.com.cn/power	视频和影像	www.ti.com.cn/video
微控制器 (MCU)	www.ti.com.cn/microcontrollers		
RFID 系统	www.ti.com.cn/rfidsys		
OMAP应用处理器	www.ti.com/omap		
无线连通性	www.ti.com.cn/wirelessconnectivity	德州仪器在线技术支持社区	www.deyisupport.com

邮寄地址: 上海市浦东新区世纪大道1568号, 中建大厦32楼邮政编码: 200122
Copyright © 2015, 德州仪器半导体技术(上海)有限公司

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS610981DSER	WSO	DSE	6	3000	178.0	8.4	1.7	1.7	0.95	4.0	8.0	Q2
TPS610981DSET	WSO	DSE	6	250	178.0	8.4	1.7	1.7	0.95	4.0	8.0	Q2
TPS610982DSER	WSO	DSE	6	3000	178.0	8.4	1.7	1.7	0.95	4.0	8.0	Q2
TPS610982DSET	WSO	DSE	6	250	178.0	8.4	1.7	1.7	0.95	4.0	8.0	Q2
TPS61098DSER	WSO	DSE	6	3000	178.0	8.4	1.7	1.7	0.95	4.0	8.0	Q2
TPS61098DSET	WSO	DSE	6	250	178.0	8.4	1.7	1.7	0.95	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS610981DSER	WSON	DSE	6	3000	205.0	200.0	33.0
TPS610981DSET	WSON	DSE	6	250	205.0	200.0	33.0
TPS610982DSER	WSON	DSE	6	3000	205.0	200.0	33.0
TPS610982DSET	WSON	DSE	6	250	205.0	200.0	33.0
TPS61098DSER	WSON	DSE	6	3000	205.0	200.0	33.0
TPS61098DSET	WSON	DSE	6	250	205.0	200.0	33.0

DSE (S-PDSO-N6)

PLASTIC SMALL OUTLINE

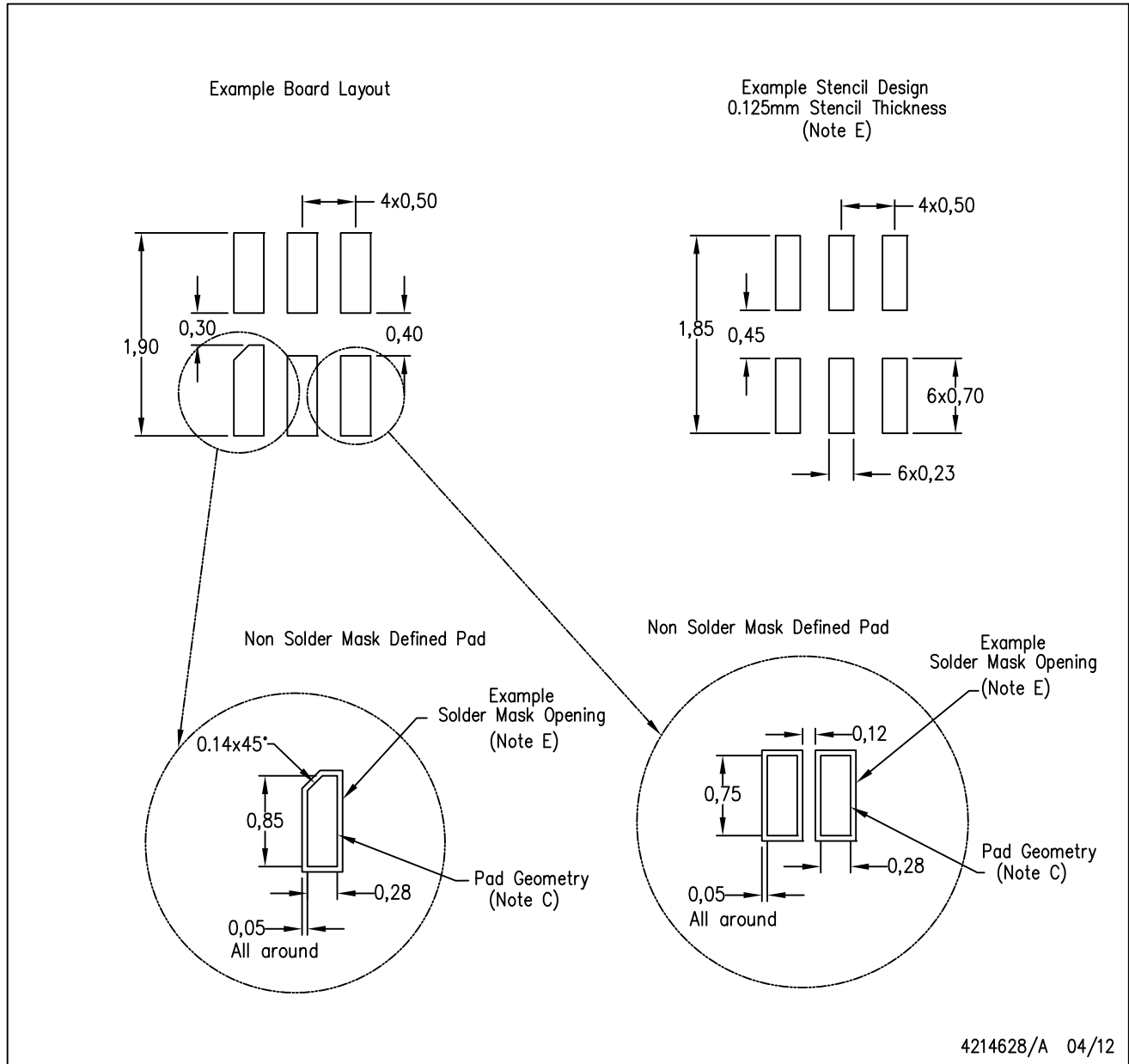


4207810/A 03/06

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Small Outline No-Lead (SON) package configuration.
 - D. This package is lead-free.

DSE (S-PWSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - E. Customers should contact their board fabrication site for solder mask tolerances.

重要声明和免责声明

TI 均以“原样”提供技术性及其可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证其中不含任何瑕疵，且不做任何明示或暗示的担保，包括但不限于对适销性、适合某特定用途或不侵犯任何第三方知识产权的暗示担保。

所述资源可供专业开发人员应用TI 产品进行设计使用。您将对以下行为独自承担全部责任：(1) 针对您的应用选择合适的TI 产品；(2) 设计、验证并测试您的应用；(3) 确保您的应用满足相应标准以及任何其他安全、安保或其他要求。所述资源如有变更，恕不另行通知。TI 对您使用所述资源的授权仅限于开发资源所涉及TI 产品的相关应用。除此之外不得复制或展示所述资源，也不提供其它TI 或任何第三方的知识产权授权许可。如因使用所述资源而产生任何索赔、赔偿、成本、损失及债务等，TI 对此概不负责，并且您须赔偿由此对TI 及其代表造成的损害。

TI 所提供产品均受TI 的销售条款 (<http://www.ti.com.cn/zh-cn/legal/termsofsale.html>) 以及ti.com.cn上或随附TI产品提供的其他可适用条款的约束。TI提供所述资源并不扩展或以其他方式更改TI 针对TI 产品所发布的可适用的担保范围或担保免责声明。

邮寄地址：上海市浦东新区世纪大道 1568 号中建大厦 32 楼，邮政编码：200122
Copyright © 2019 德州仪器半导体技术（上海）有限公司